

Excited Carrier Dynamics in Condensed Matter System

From ab initio simulation

Jin Zhao

University of Science and Technology of China

Back ground

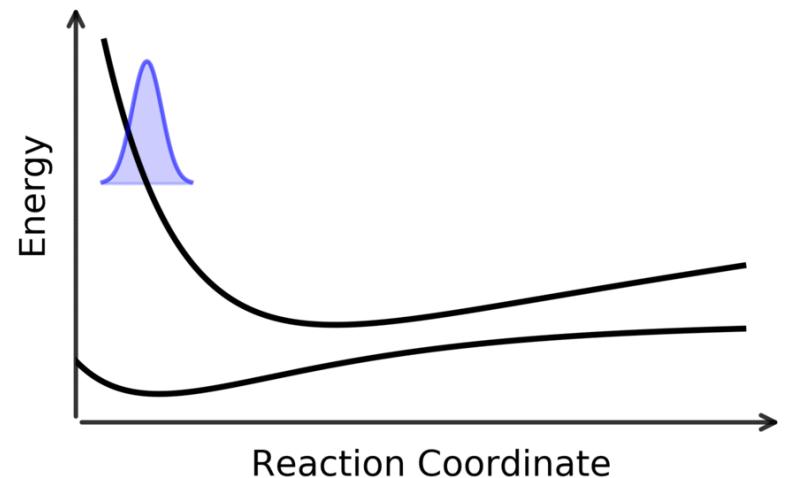
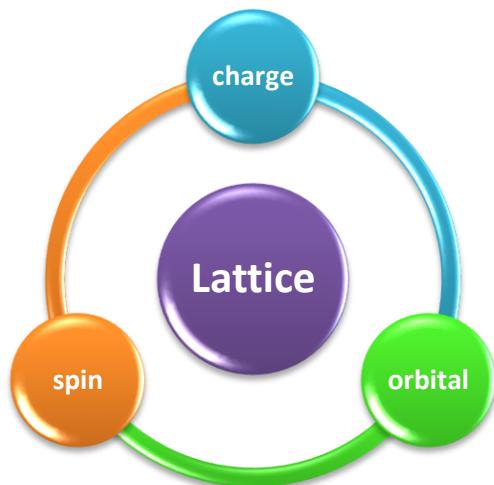
Single particle dynamics

Spin dynamics

Exciton Dynamics

Outlook

Carrier Dynamics in Condensed Matter Systems



Condensed matter physics: **Charge, spin and orbital**

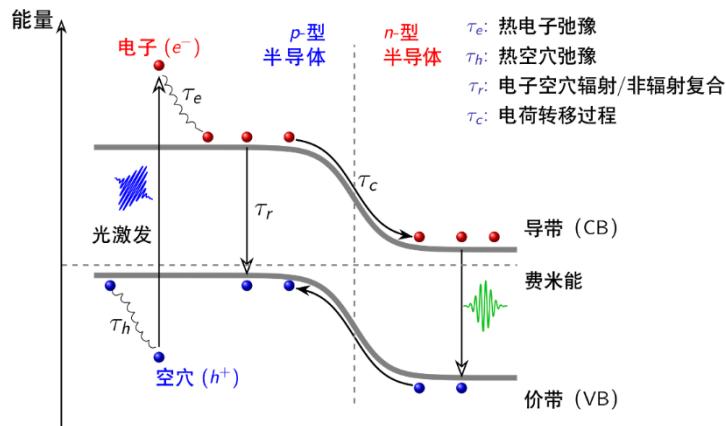
Important tool: **First principles calculations**

$$\mathcal{H}\psi = E\psi$$

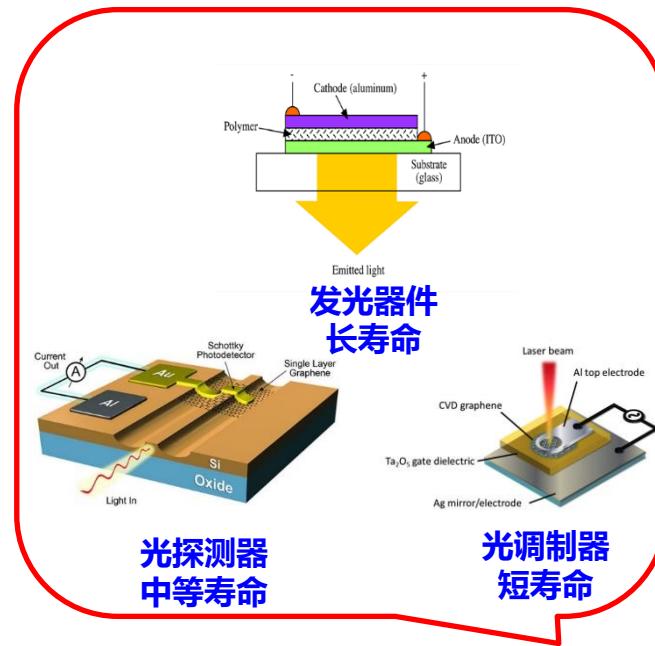
$$i\hbar \frac{\partial}{\partial t} \psi = \mathcal{H}\psi$$

Multi-dimension: **energy, momentum, real space, spin, time**

Applications of Photoexcited Carrier Dynamics



太阳能电池各种载流子动力学
行为共同决定效率

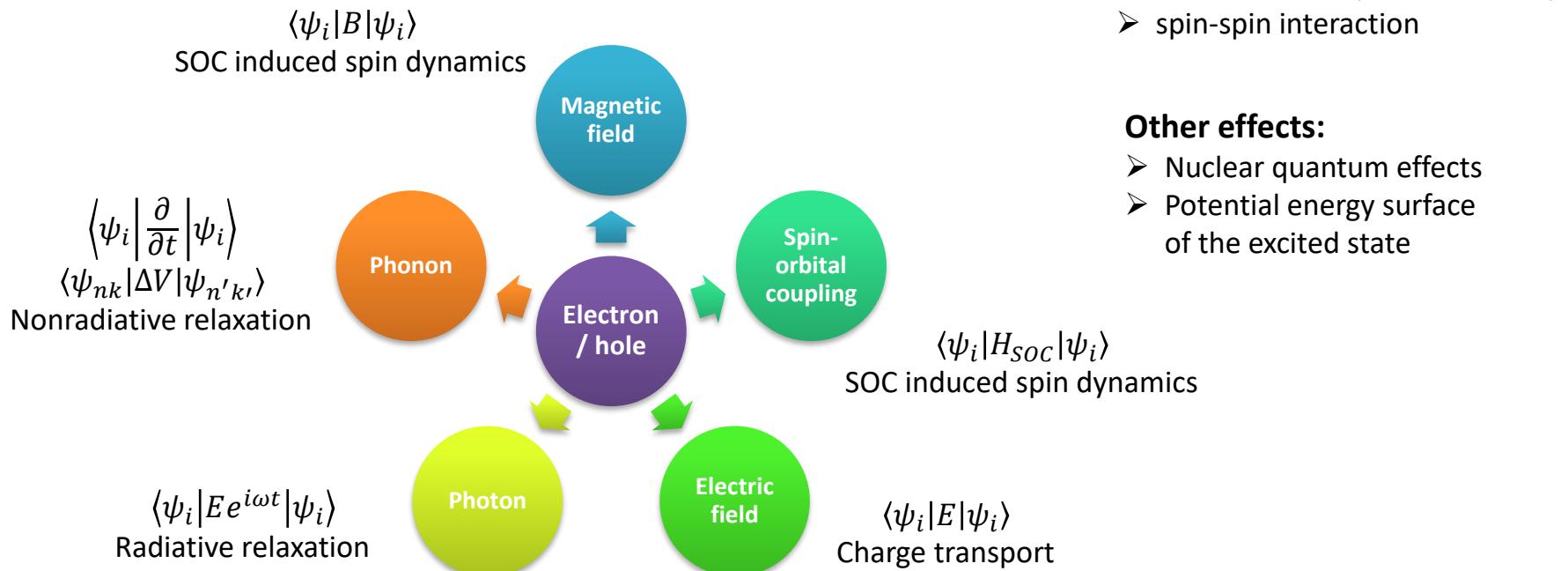


不同光电器件对材料载
流子寿命有不同要求

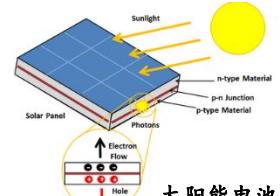
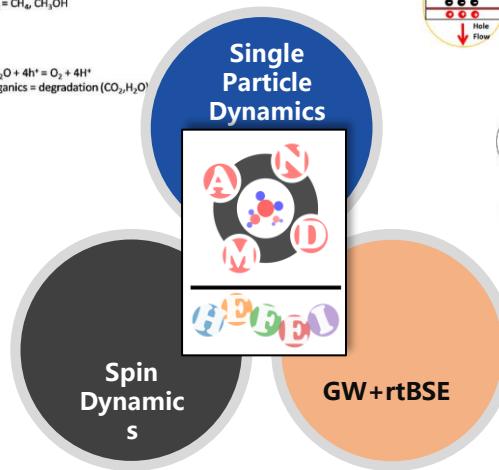
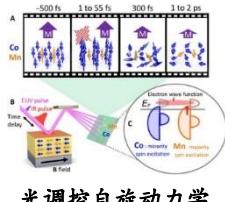
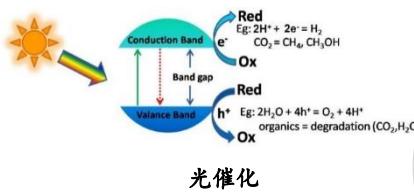
Determining Factors of Carrier Dynamics

No perturbation, no relaxation : $\langle \psi_i | \psi_j \rangle = 0$

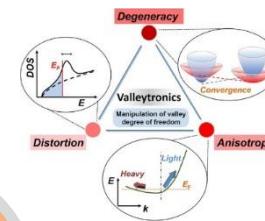
With perturbation:



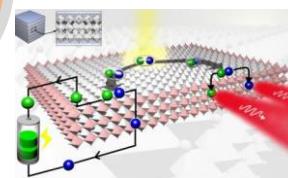
Ab initio Code for Excited Carrier Dynamics



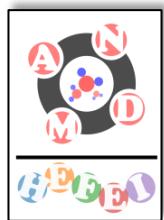
太阳能电池



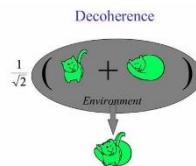
谷电子学



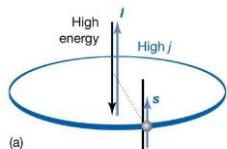
Hefei-NAMD



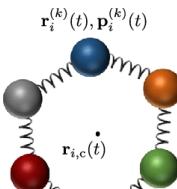
Quantum decoherence Spin-orbital Coupling



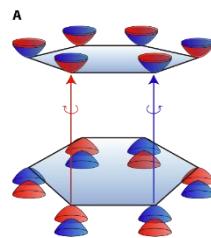
Spin-orbital Coupling



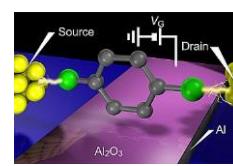
Nuclear Quantum effects



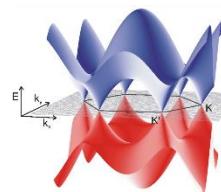
GW + real-time BSE



Charge transport



Dynamics in momentum space



2016



郑奇靖

2018



褚维斌

2018



郑奇靖

2018



褚维斌

2021



蒋翔

now



田韫哲

now



郑镇法



赵传寓



史永亮

Back ground

Single particle dynamics

Spin dynamics

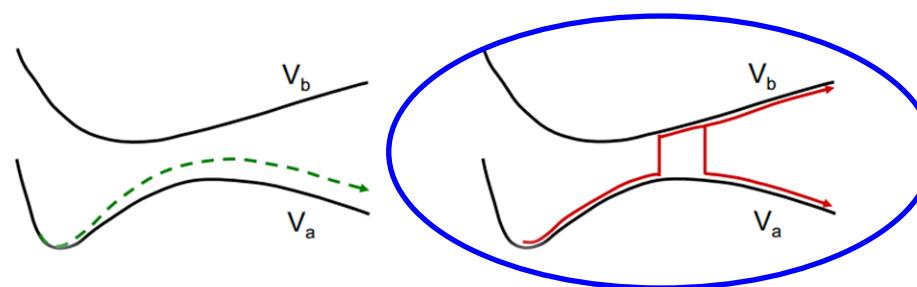
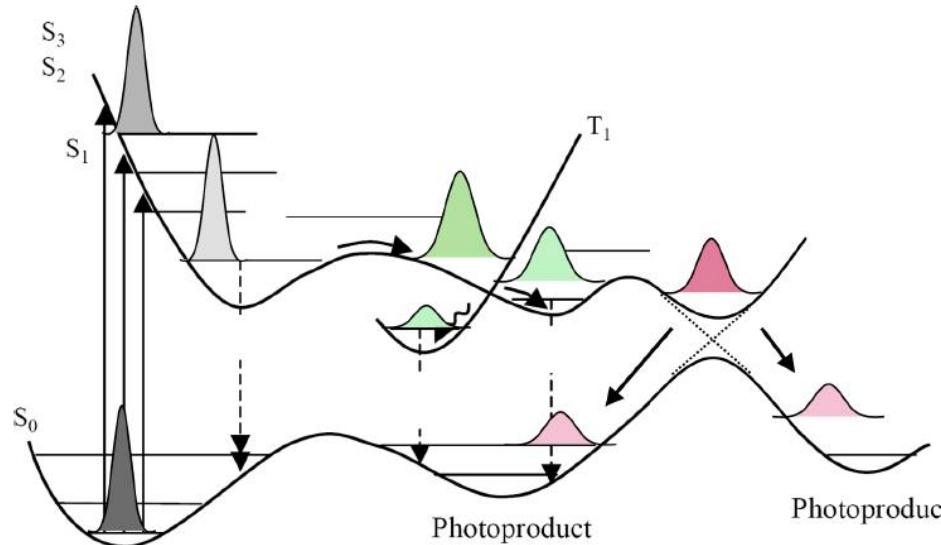
Exciton Dynamics

Outlook

Beyond Born-Oppenheimer Approximation

Mixed Quantum-Classical approximation

$$\Psi(\mathbf{r}, \mathbf{R}, t) = \Omega_j(\mathbf{R}, t)\Phi_j(\mathbf{r}; \mathbf{R}); \quad \hat{\mathcal{H}}_{el}(\mathbf{r}; \mathbf{R})\Phi_j(\mathbf{r}; \mathbf{R}) = E_j(\mathbf{R})\Phi_j(\mathbf{r}; \mathbf{R})$$



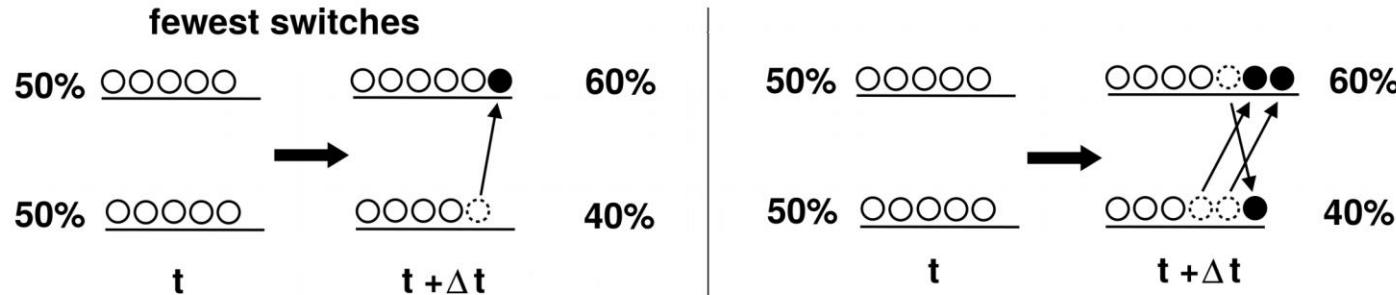
Ehrenfest Dynamics

Surface Hopping

$$M_\alpha \ddot{\mathbf{R}}_\alpha = -\nabla_\alpha \langle \hat{\mathcal{H}}_{el}(\mathbf{r}, \mathbf{R}) \rangle$$

$$M_\alpha \ddot{\mathbf{R}}_\alpha = -\nabla_\alpha E_k^{el}(\mathbf{R})$$

Fewest surface hopping



Assumptions

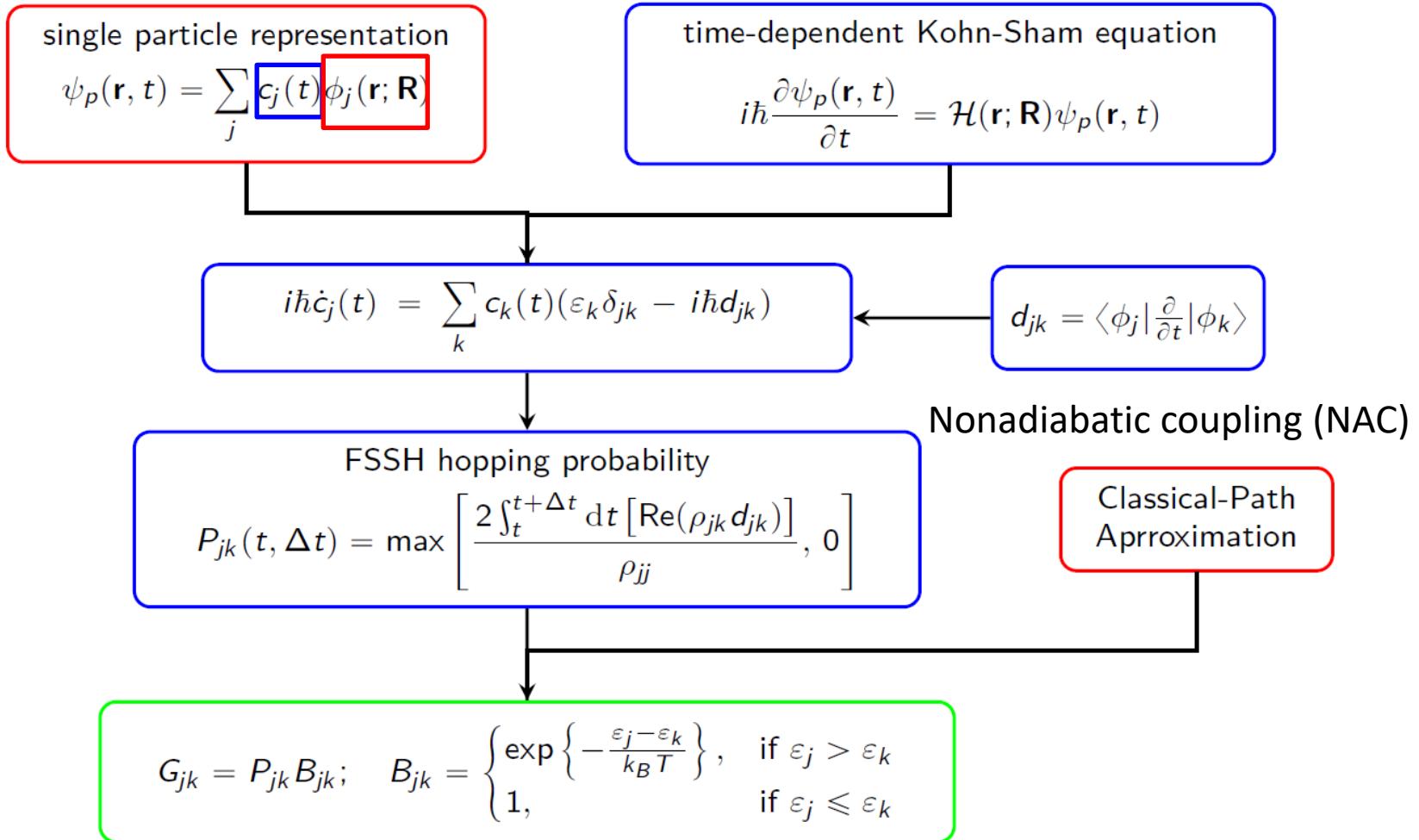
- Ensemble of independent trajectories have same coefficients $C_j(t)$.
- Internal consistency condition $N_j(t) \propto C_j^*(t)C_j(t) = \rho_{jj}(t)$.
- Hops from j to different $k \neq j$ are independent.
- Overall trajectory hops should be minimum.

Fewest-Switches: Hopping Probability

Transition from current state j to state $k \neq j$ is allowed only if population of state j is **decreasing**.

$$P_{jk}(t, \Delta t) = \max\left(-\frac{2 \int_t^{t+\Delta t} dt \left[\hbar^{-1} \operatorname{Im}(\rho_{jk} H_{jk}) - \operatorname{Re}(\rho_{jk} \mathbf{d}_{jk} \cdot \dot{\mathbf{R}}) \right]}{\rho_{jj}}, 0\right)$$

Surface Hopping Combined with TDKS



A. Akimov and O. Prezhdo: Pyxaid

Q. Zheng, X. Jiang, et. al. J. Zhao: Hefei-NAMD

Electron-phonon interaction – Nonadiabatic coupling

$$H_{ki} = \epsilon_k \delta_{ik} - i\hbar \left\langle k \left| \frac{\partial}{\partial t} \right| i \right\rangle$$

Nonadiabatic coupling

$$d_{jk} = \left\langle \varphi_j \left| \frac{\partial}{\partial t} \right| \varphi_k \right\rangle$$

$$= \frac{\langle \varphi_j | \nabla_R H | \varphi_k \rangle}{\epsilon_k - \epsilon_j} \dot{R}$$

Electron-phonon matrix elements

$$\mathbf{d}_{jk} = \langle \phi_j | \frac{\partial}{\partial t} | \phi_k \rangle$$

$$= \frac{\langle \phi_j(t) | \phi_k(t + \Delta t) \rangle - \langle \phi_j(t + \Delta t) | \phi_k(t) \rangle}{2\Delta t}$$

- ✓ charge transfer dynamics
- ✓ Electron-hole recombination

Electron-phonon interaction - Decoherence Correction

退相干时间

纯退相干时间（根据光响应理论）

$$D(t) = \exp(i\omega t) \left\langle -\frac{i}{\hbar} \int_0^t \Delta E d(\tau) t \right\rangle$$

能级差（右图一）

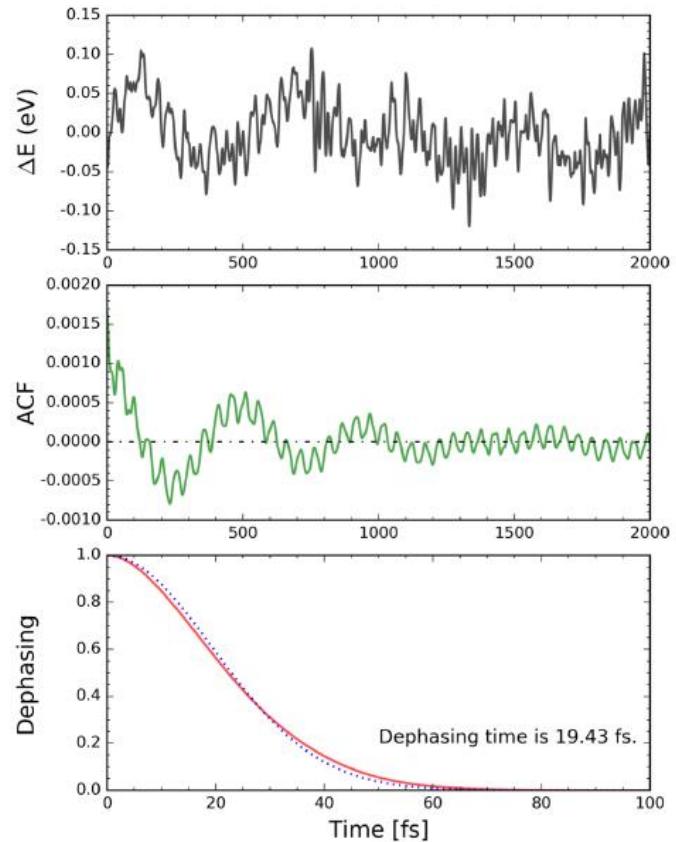
$$\Delta E = \Delta E_{ij} - \langle \Delta E_{ij} \rangle_T$$

自关联函数（右图二）

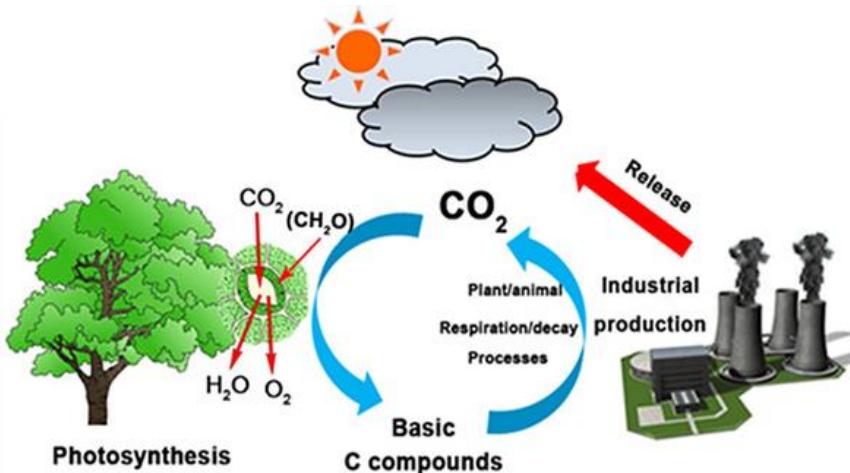
$$C(t) = \langle \Delta E(\tau) \Delta E(0) \rangle$$

退相干函数（二次卷积形式，右图三）

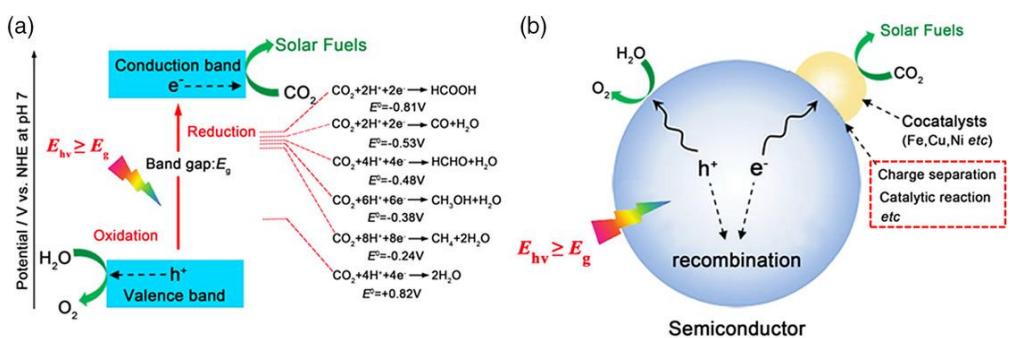
$$D(t) = \exp \left(-\frac{1}{\hbar^2} \int_0^t d\tau_1 \int_0^{\tau_1} d\tau_2 \langle \Delta E(t) \cdot \Delta E(0) \rangle \right)$$



What is Photocatalysis

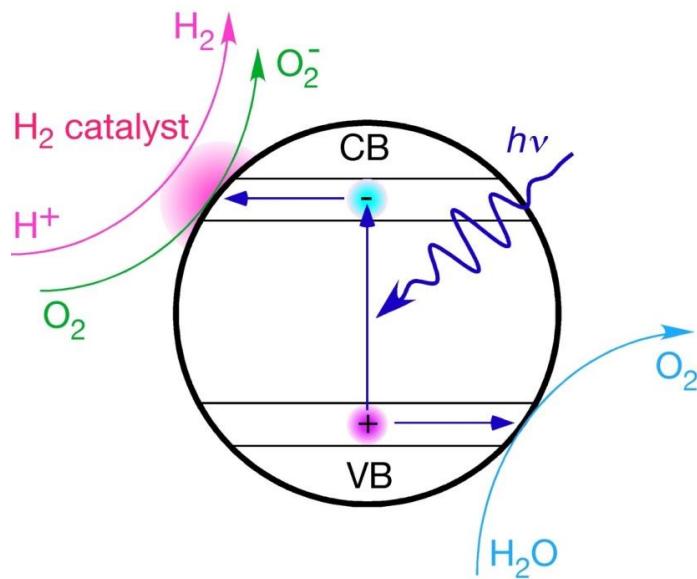


- ✓ 光解水
- ✓ 光还原 CO_2
- ✓ 降解污染物
- ...



目标：通过第一性原理计算理解光催化反应机制，提出理论设计提升反
应效率

Crucial Processes in Photocatalysis on Surfaces



- ✓ **Photo-absorption**
absorption spectra (DFT, GW+BSE)
- ✓ **Photoexcited carrier trapping**
Lifetime of photoexcited carriers
Carrier migration to surface
Carrier trapping by molecules
- ✓ **Photochemical reaction on the surface**
Excited state reaction barrier

Crucial Processes in Photocatalysis on Surfaces

- ✓ Photo-absorption

- absorption spectra (DFT, GW+BSE)

- ✓ Photoexcited carrier trapping

- Lifetime of photoexcited carriers

- Carrier migration to surface

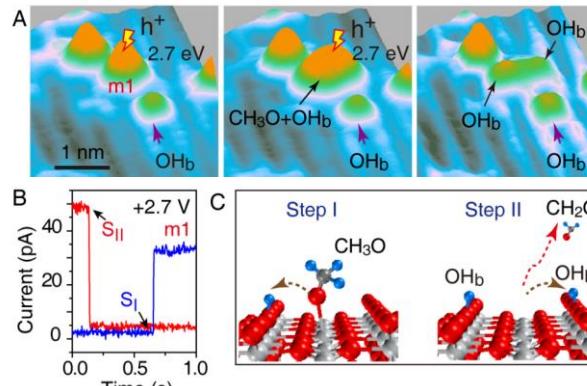
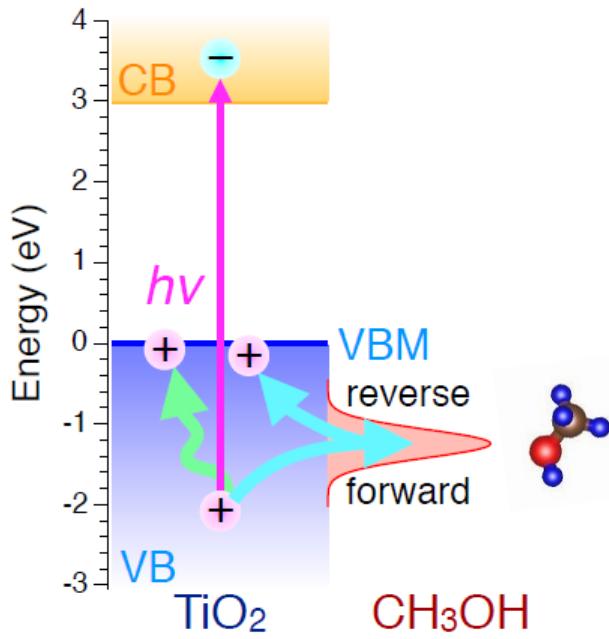
- Carrier trapping by molecules

- ✓ Photochemical reaction on the surface

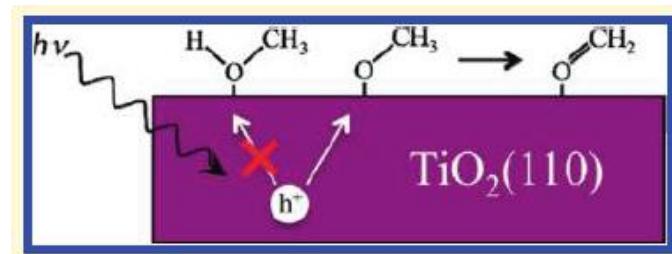
- Excited state reaction barrier

Excited Carrier Dynamics

CH_3OH behaves as a hole scavenger on TiO_2



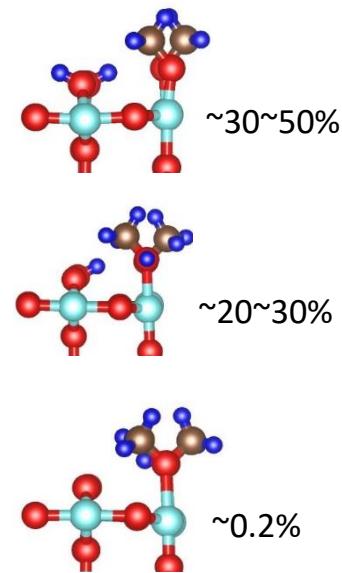
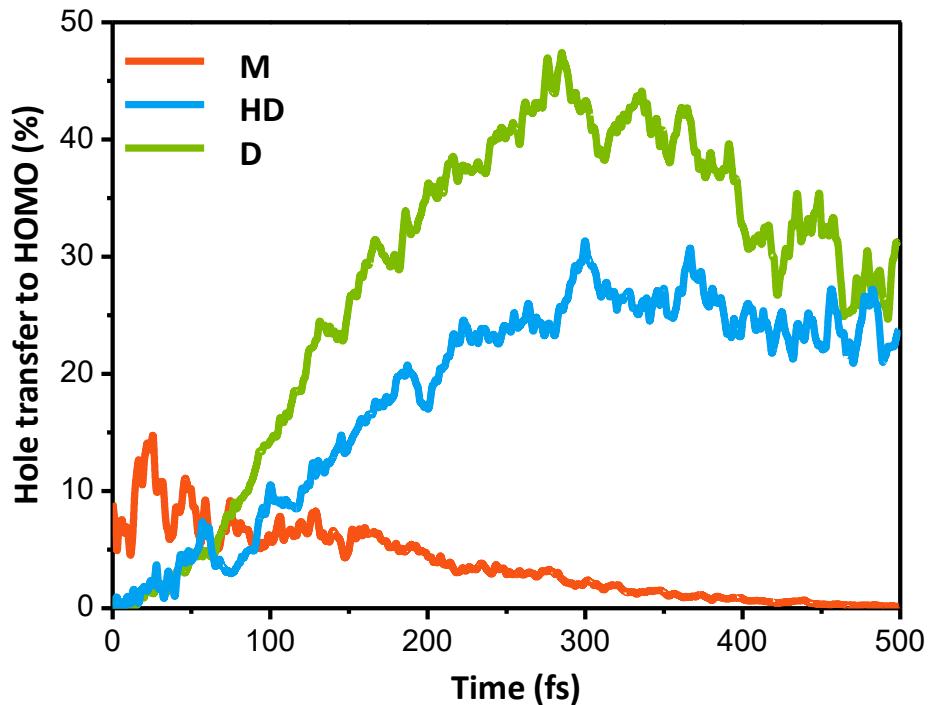
Hole induced dissociation of CH_3OH on TiO_2 observed by Bing Wang et.al.



Henderson et.al. believes that CH_3O is the hole trapper in stead of CH_3OH

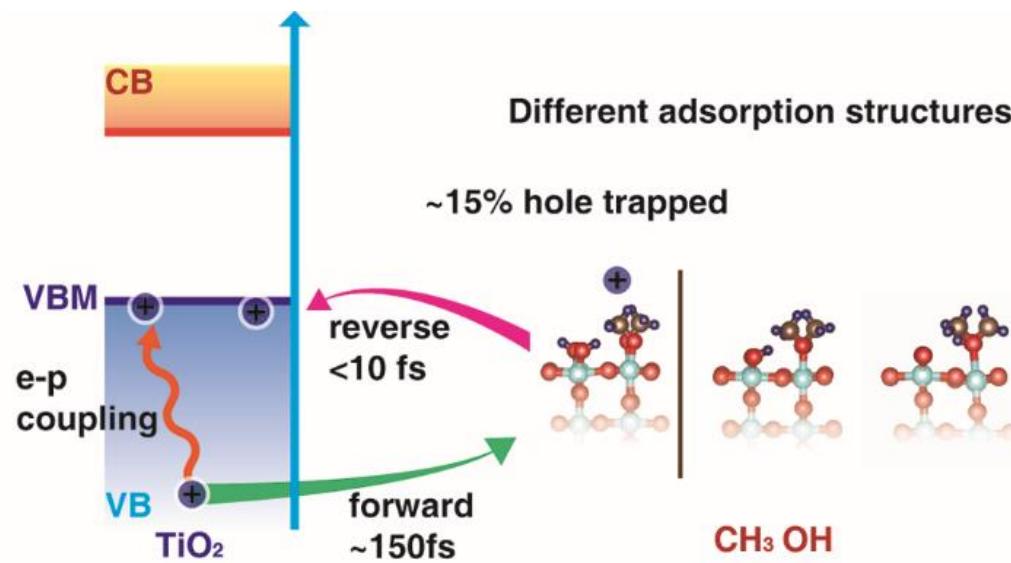
M. Shen and M. A. Henderson, *J. Phys. Chem. Lett.* **2**, 2707-2710 (2011)

Hole trapping sites



Average from 10^5 trajectories

CH_3OH as a Hole Scavenger on TiO_2 Surface



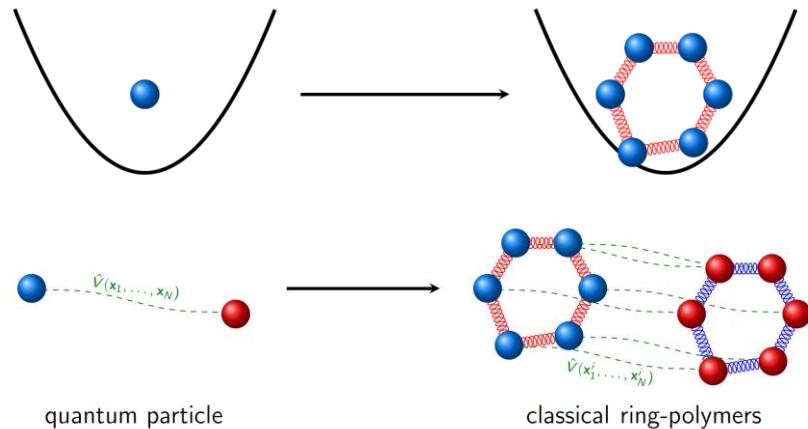
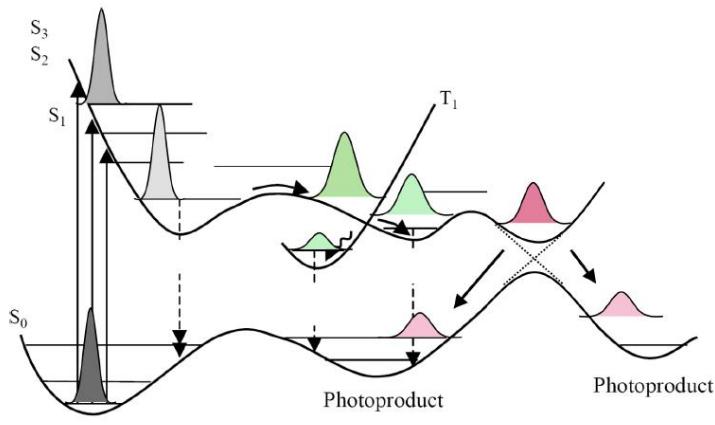
W. Chu, W. A. Saidi, Q. Zheng*, Y. Xie, Z. Lan, O. V. Prezhdo, H. Petek and **J. Zhao*** *J. Am. Chem. Soc.*, 138, 13740, (2016)

Nuclear Quantum Effects in NAMD

Mixed Quantum-Classical

approximation

$$\psi(\mathbf{r}, \mathbf{R}) \approx \Psi_{\text{QM}}(\mathbf{r}; \mathbf{R}) \Psi_{\text{RPMD}}(\mathbf{r}; \mathbf{R}); \quad \hat{\mathcal{H}}_{\text{el}}(\mathbf{r}; \mathbf{R}) \Phi_j(\mathbf{r}; \mathbf{R}) = E_j(\mathbf{R}) \Phi_j(\mathbf{r}; \mathbf{R})$$

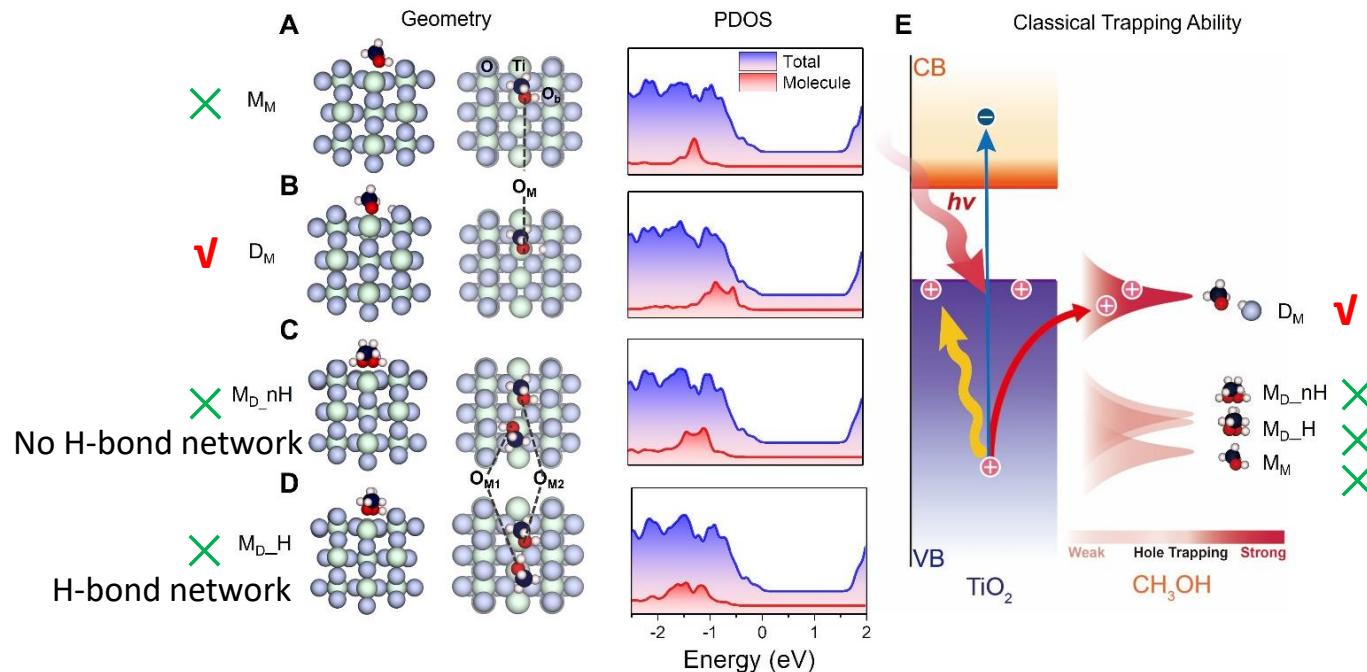


Ring-polymer molecular dynamics (RPMD)

Q: 如何在mixed quantum-classical approximation中考慮核量子效應

A: RPMD + NAMD

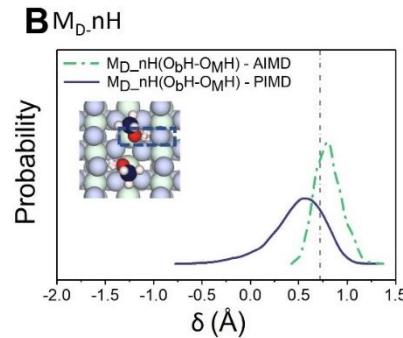
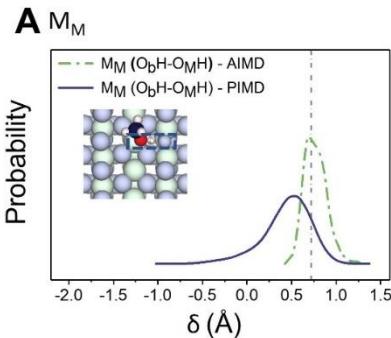
Different Adsorption Structures of CH_3OH on TiO_2



Dissociated CH_3O (D_M) behaves as hole scavenger

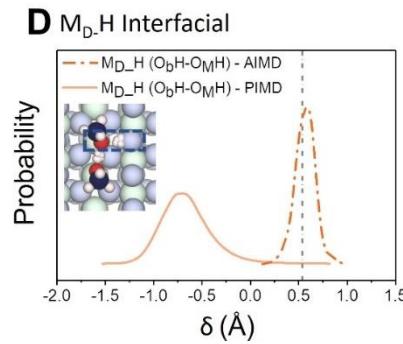
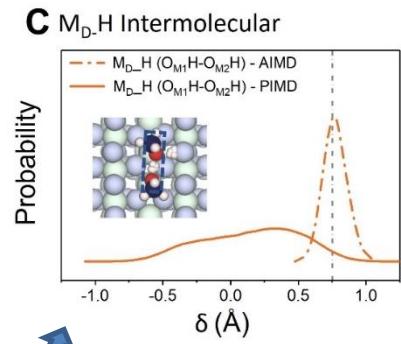
Nuclear Quantum effects (NQEs) on the Adsorption Structures

No H-bond network



$$\delta = R_{\text{O}_a\text{H}} - R_{\text{O}_d\text{H}}$$

H-bond network

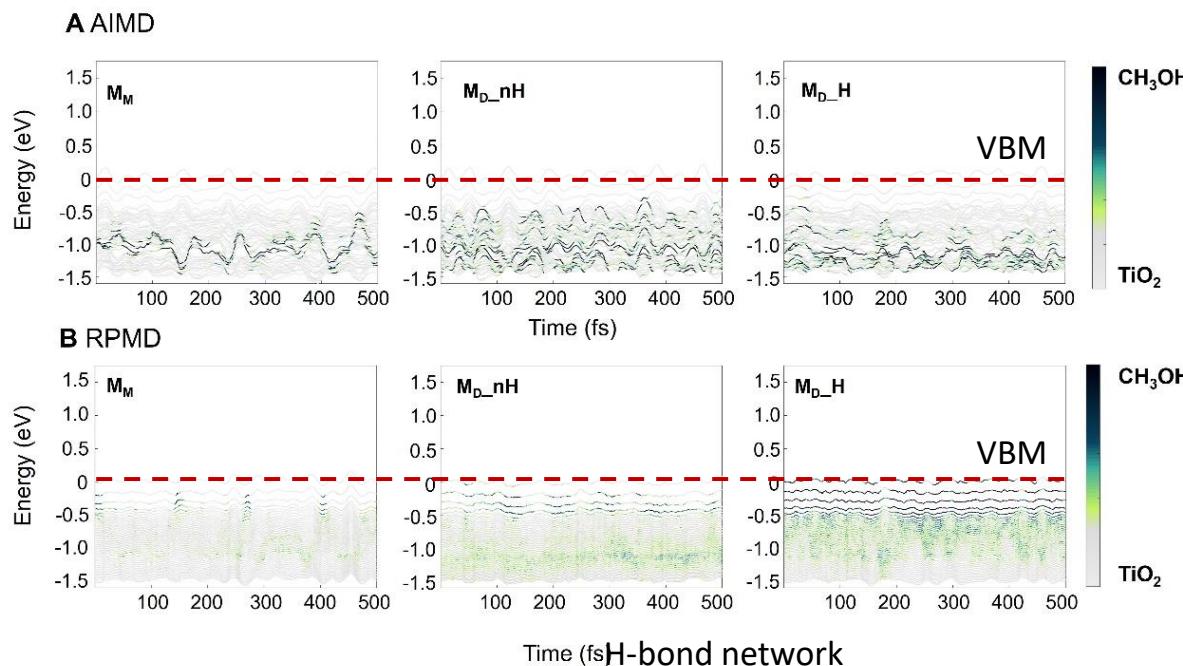


$\delta > 0$ no proton transfer
 $\delta < 0$ proton transfer

Quantum proton delocalization

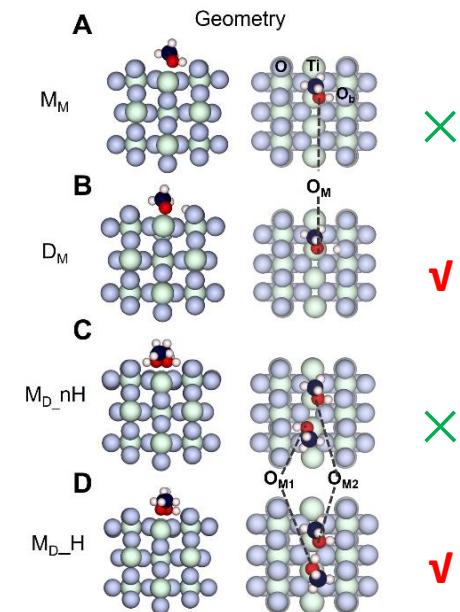
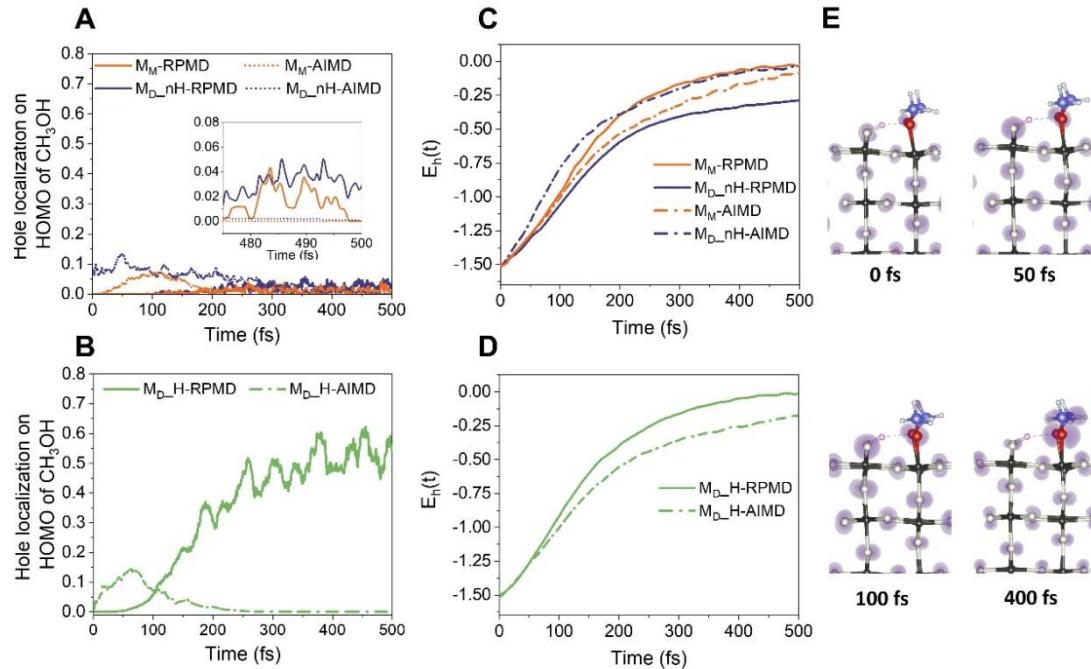
NQEs induced proton transfer

Nuclear Quantum effects on the Energy Level Alignment



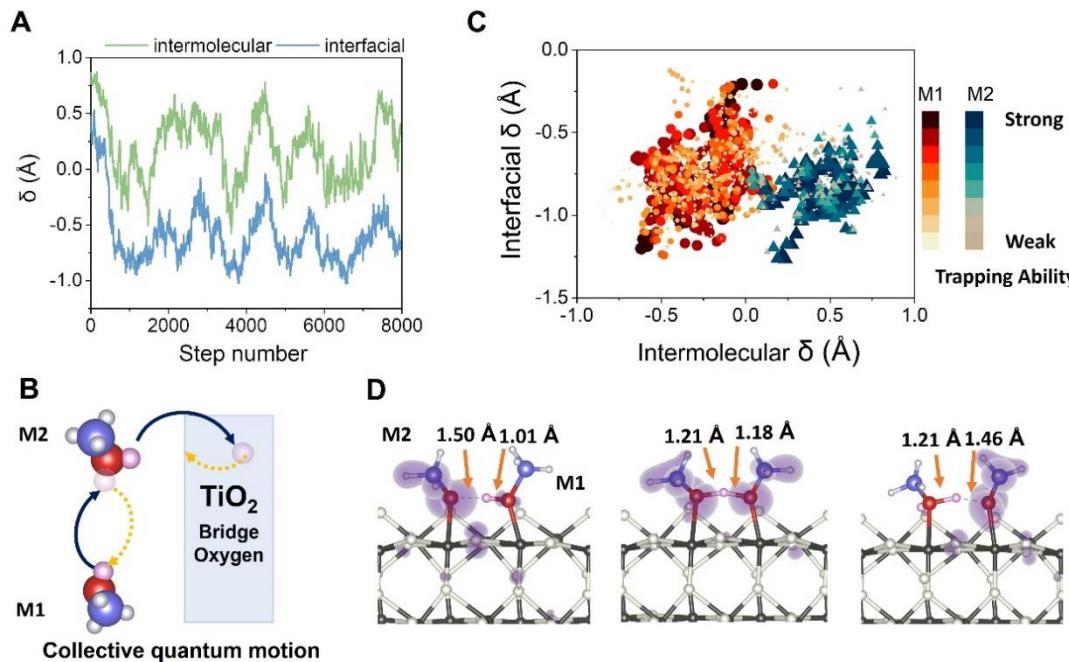
NQEs change the band alignment of M_{D-H} system, where a H-bond network is formed.

Nuclear Quantum Effects on Hole Trapping



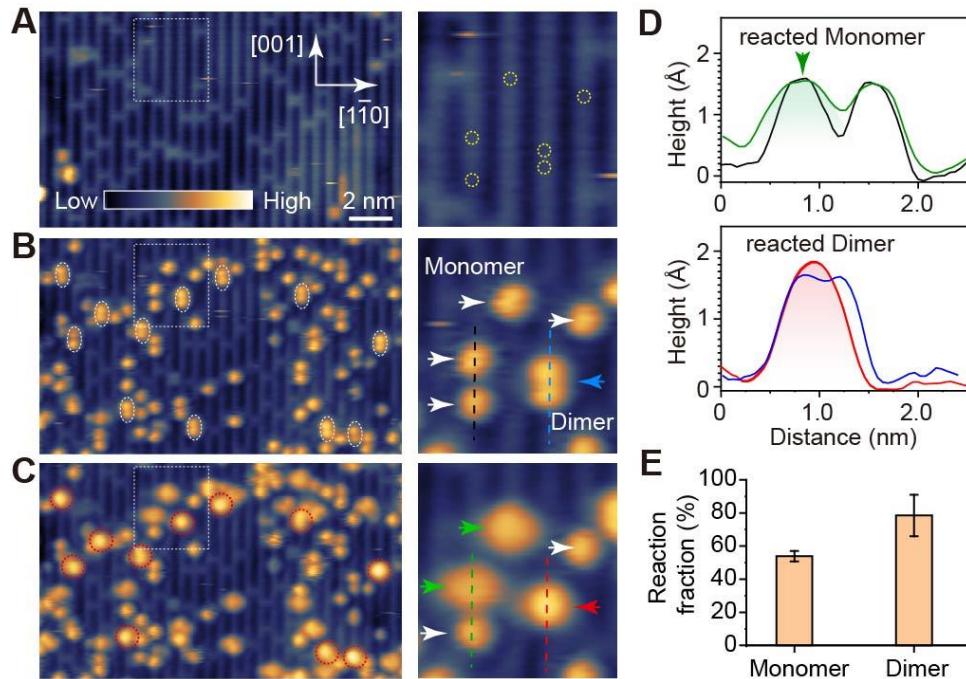
NQEs makes M_D -H behave as a hole scavenger.

Collective Nuclear Quantum Motion Coupled Hole Transfer



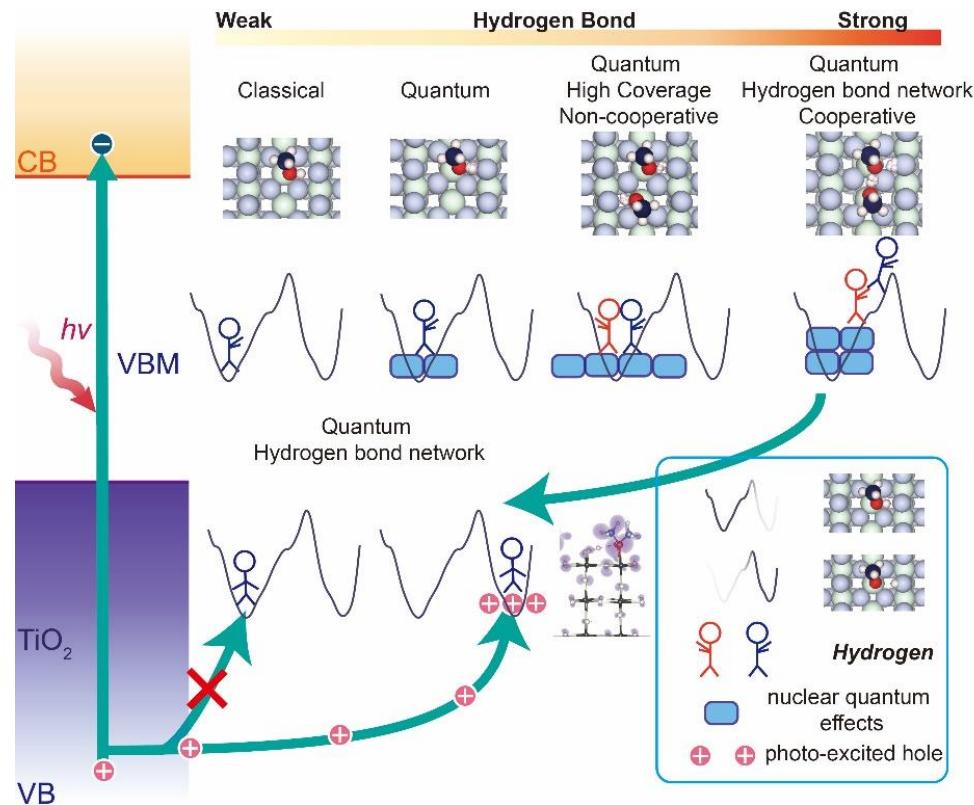
In the H-bond network, the quantum proton motion is collective, which couples with hole trapping dynamics.

Experimental Evidence by STM



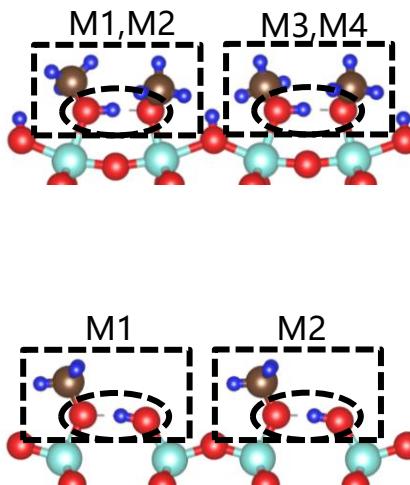
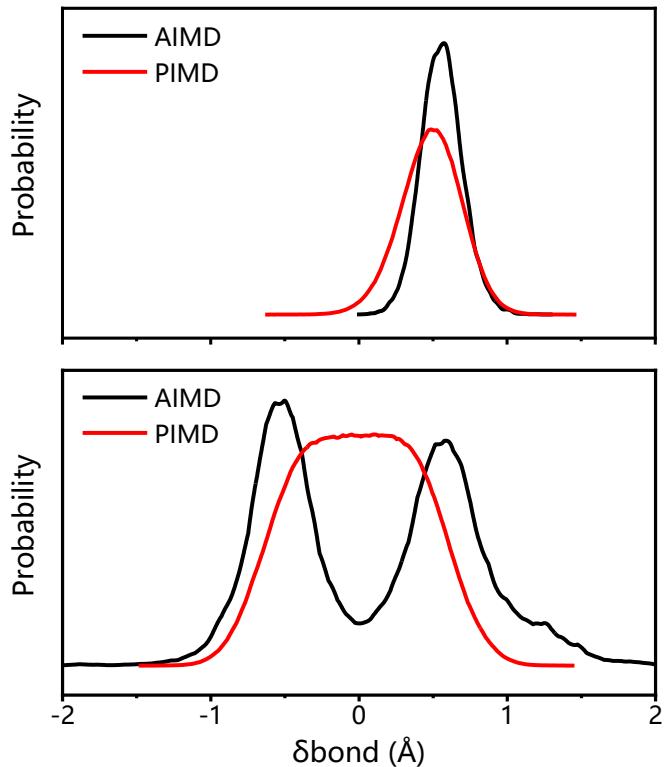
Dimer formation (H-bond network) improves the photochemical reaction rate.

Summary - Example I



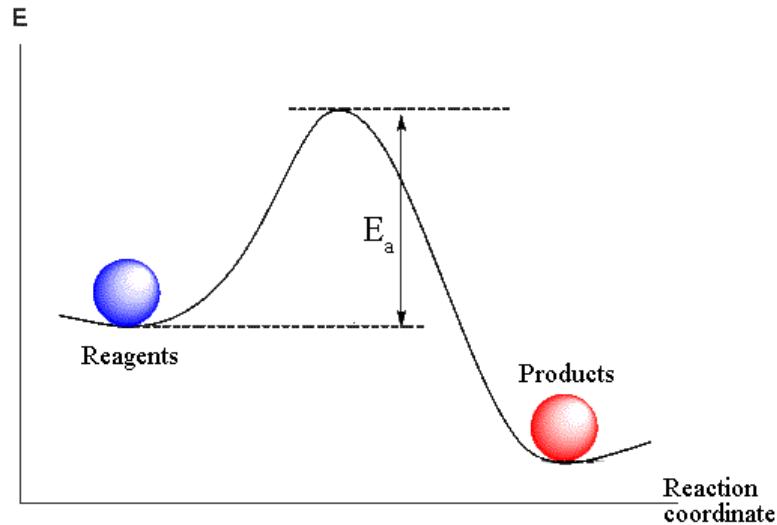
W. Chu *et al.* X. Li*, J. Zhao* *Sci. Adv.* **8**, eabo2675 (2022)

Outlook - Example I



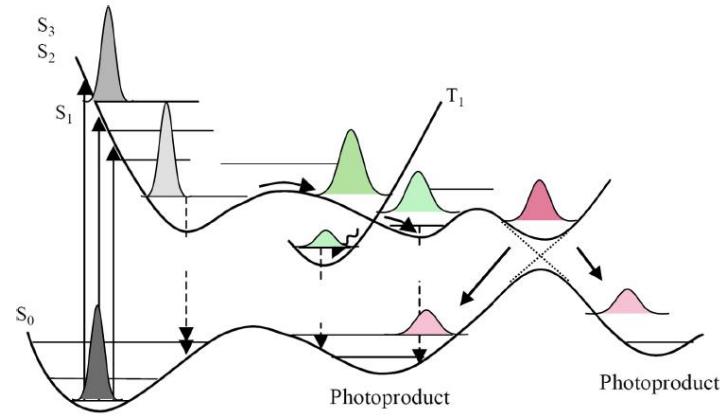
**RPMD/PIMD is very expensive!
Machine Learning + PIMD/RPMD**

Outlook - Part II



基态催化:

计算反应势垒，方法非常成熟



光催化:

- ✓ 激发态势能面
- ✓ 势能面交叉
- ✓ 激发态载流子寿命

Back ground

Single particle dynamics

Spin dynamics

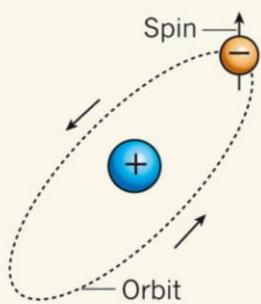
Exciton Dynamics

Outlook

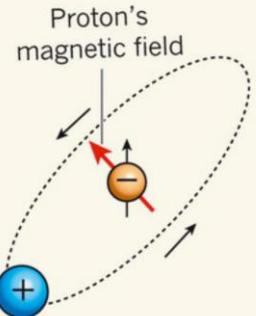
Spin Dynamics

a Electron in an atom

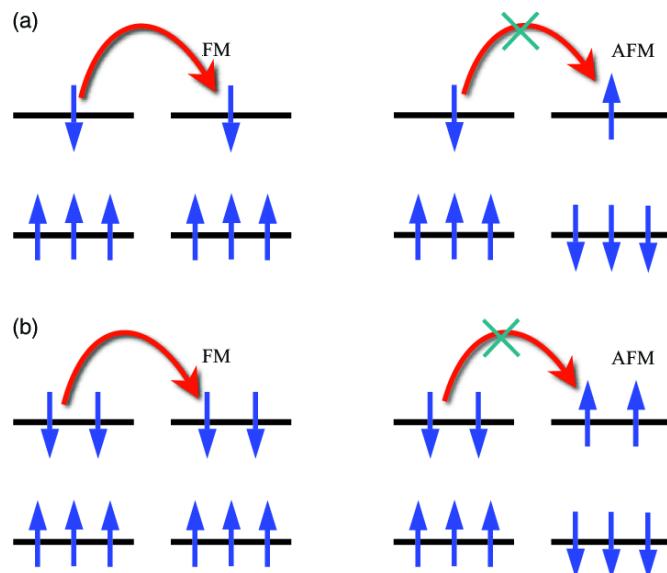
Proton's point of view



Electron's point of view

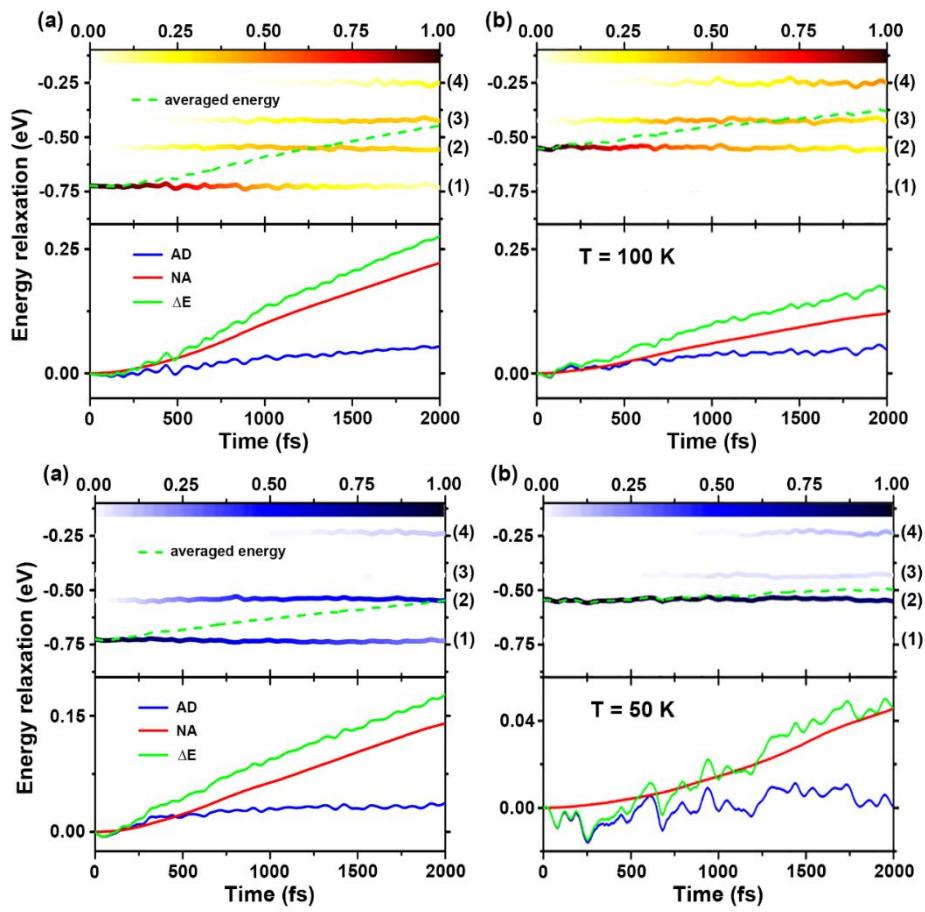
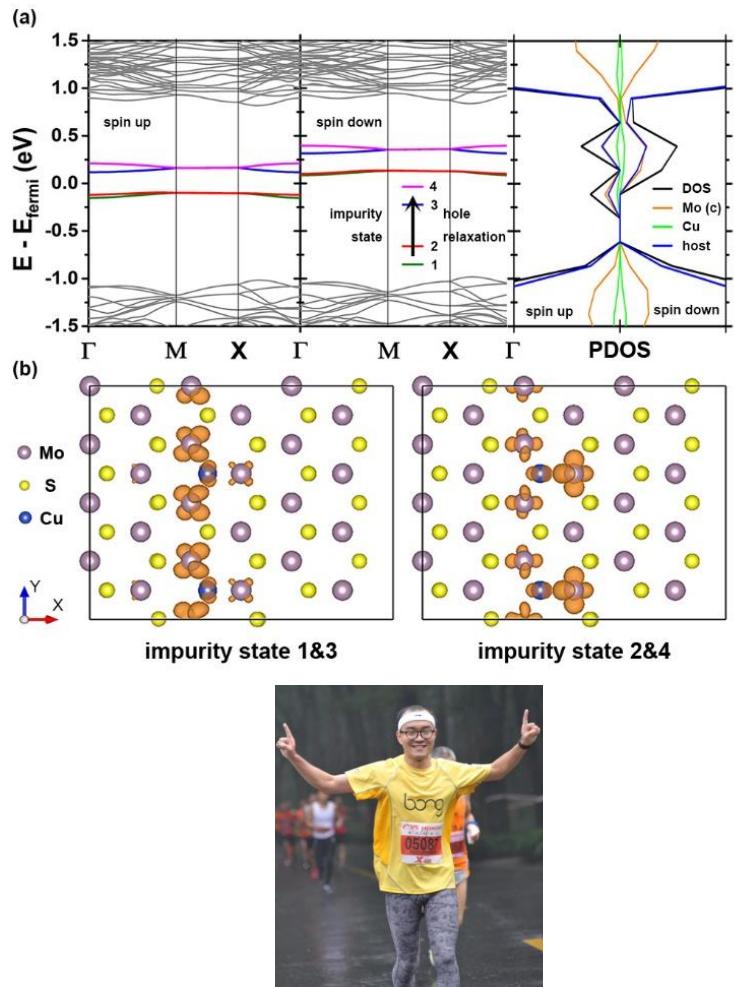


Spin-Orbital Interaction



Spin-Spin Interaction

Dynamics of Photogenerated Spin Hole Current



C. Zhao, et al. and J. Zhao*, *Phys. Rev. B* **96**, 134308 (2017)

赵传寓

NAMD with SOC

The time-dependent Schrödinger equation

$$i\hbar \frac{\partial |\Psi(\mathbf{r}, \mathbf{R}(t), \mathbf{s}, t)\rangle}{\partial t} = \hat{\mathcal{H}}^{tot}(\mathbf{r}, \mathbf{R}(t), \mathbf{s}) |\Psi(\mathbf{r}, \mathbf{R}(t), \mathbf{s}, t)\rangle \quad (1)$$

where the total Hamiltonian is given by

$$\hat{\mathcal{H}}^{tot}(\mathbf{r}, \mathbf{R}(t), \mathbf{s}) = \hat{\mathcal{H}}^0(\mathbf{r}, \mathbf{R}(t)) + \hat{\mathcal{H}}^{soc}(\mathbf{r}, \mathbf{R}(t), \mathbf{s}) \quad (2)$$

by expanding the wavefunction with a basis set $\{|\psi_i\rangle\}$ or different representations

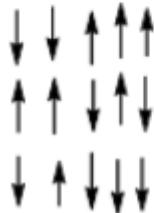
$$|\Psi\rangle = \sum_i |\psi_i\rangle \langle \psi_i| \Psi \rangle = \sum_i c_i |\psi_i\rangle \quad (3)$$

and substituting eq (3) into eq (1), we have

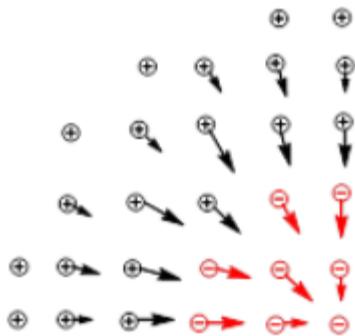
$$\begin{aligned} \frac{\partial c_j(t)}{\partial t} &= - \sum_i \left[i\hbar^{-1} \langle \psi_j | \hat{\mathcal{H}}^{tot} | \psi_i \rangle + \langle \psi_j | \frac{d}{dt} | \psi_i \rangle \right] c_i(t) \\ &= - \sum_i \left[i\hbar^{-1} \langle \psi_j | \hat{\mathcal{H}}^0 | \psi_i \rangle + i\hbar^{-1} \langle \psi_j | \hat{\mathcal{H}}^{soc} | \psi_i \rangle + \langle \psi_j | \frac{d}{dt} | \psi_i \rangle \right] c_i(t) \\ &= - \sum_i \left(i\hbar^{-1} H_{ji}^0 + i\hbar^{-1} \mathcal{H}_{ji}^{soc} + \mathcal{T}_{ji} \right) c_i(t) \end{aligned} \quad (4)$$

Choices of Representations

Ising Model –
vectors point
UP OR DOWN
ONLY → simplest



Heisenberg Model –
vectors point in
any direction
IN SPACE



- “Spin-diabatic” representation

- $H_{ji}^0 = E_j \delta_{ji}$, i.e. $\{|\psi_i\rangle\} \Rightarrow$ eigenstates of $\hat{\mathcal{H}}^0$.
- $H_{ji}^{soc} = 0$ for same spin multiplicity.
- $T_{ji} = 0$ for different spin multiplicity.
- Used with weak SOC.

- “Spin-adiabatic” representation

- $H_{ji}^0 + H_{ji}^{soc} = \Lambda_j \delta_{ji}$, i.e. $\{|\psi_i\rangle\} \Rightarrow$ eigenstates of $\hat{\mathcal{H}}^{tot}$.
- Hopping solely determined by T_{ji} .
- Strong SOC.

The hopping probability within FSSH

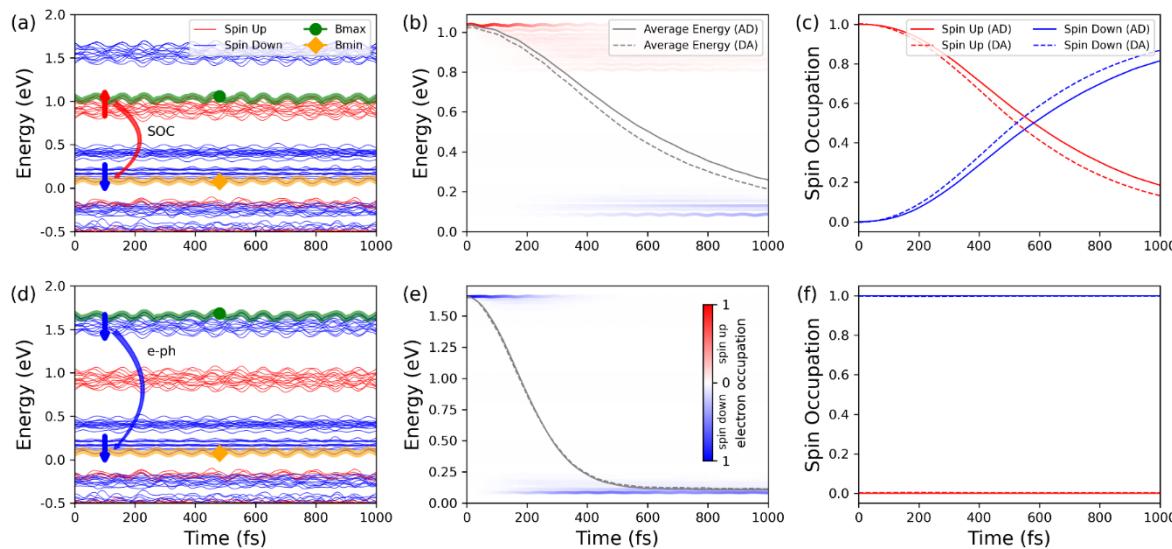
$$P_{j \rightarrow k}(t, \Delta t) = \max \left(-\frac{2\Delta t [\hbar^{-1} \operatorname{Im}(c_j^* c_k (H_{jk}^0 + H_{jk}^{soc})) - \operatorname{Re}(c_j^* c_k T_{jk})]}{c_j^* c_j}, 0 \right)$$



郑奇靖

Ni金属自旋轨道耦合引发超快退磁过程

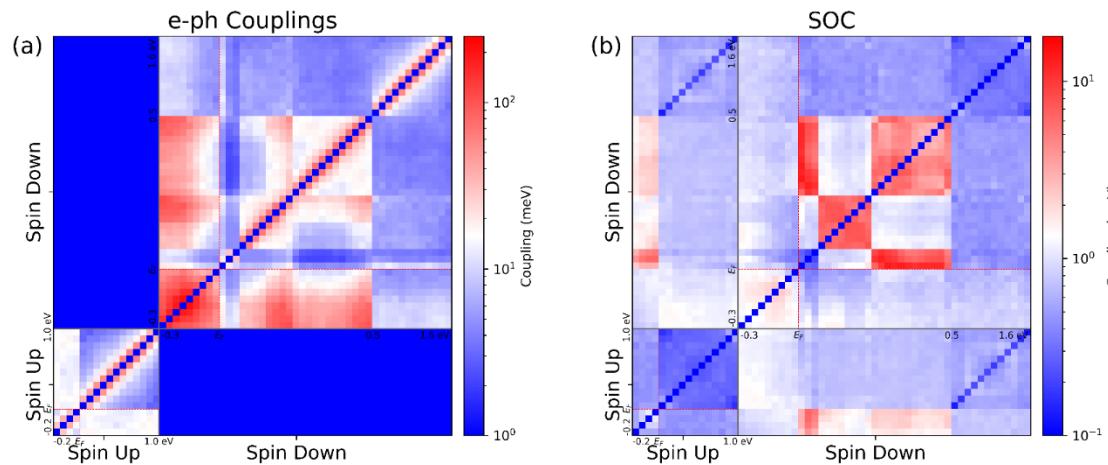
Spin up electrons **will** flip to Spin down electrons due to SOC



Spin down electrons **will NOT** flip to Spin up electrons due to SOC
They will decay to spin down electrons with lower energies.

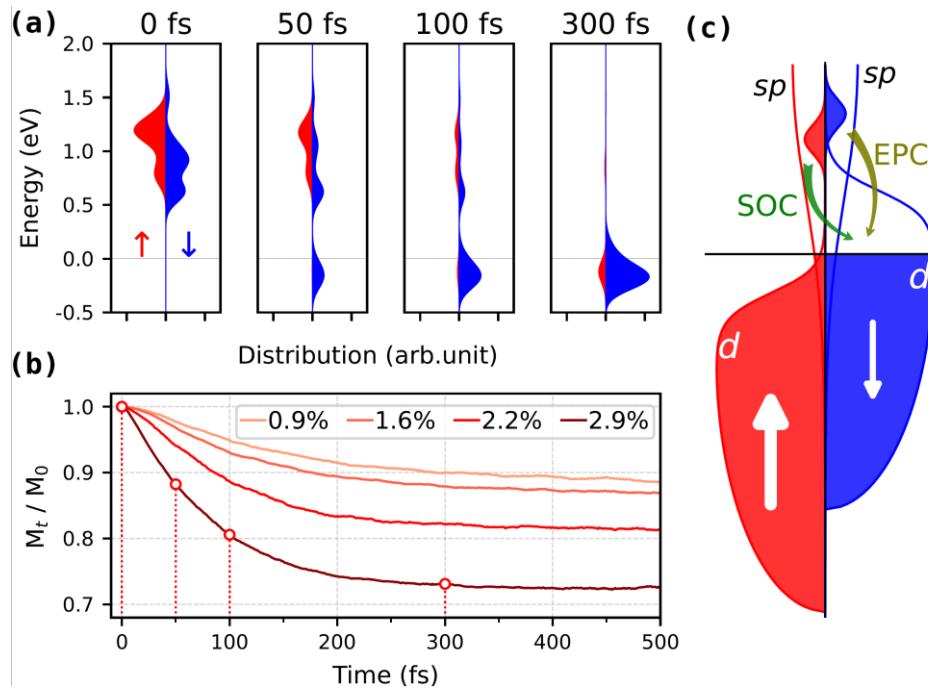
自旋轨道耦合与电声耦合

$$H_{ki} = \epsilon_k \delta_{ik} - i\hbar \left\langle k \left| \frac{\partial}{\partial t} \right| i \right\rangle + i\hbar \langle k | \mathcal{H}^{SOC} | i \rangle$$



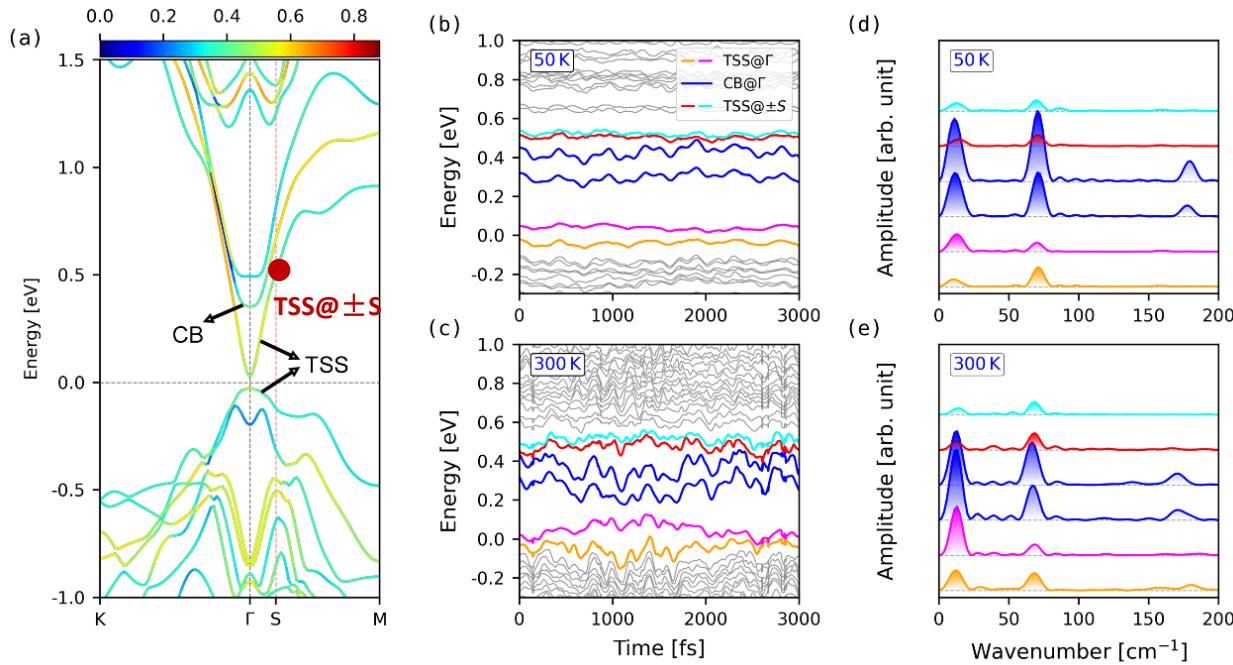
In Ni, e-ph coupling > SOC. The electron tends to decay through the orbitals with the same spin.

Ni体系超快退磁



Z. Zheng, Q. Zheng*, J. Zhao*, *Phys. Rev. B* **105**, 085142 (2022)

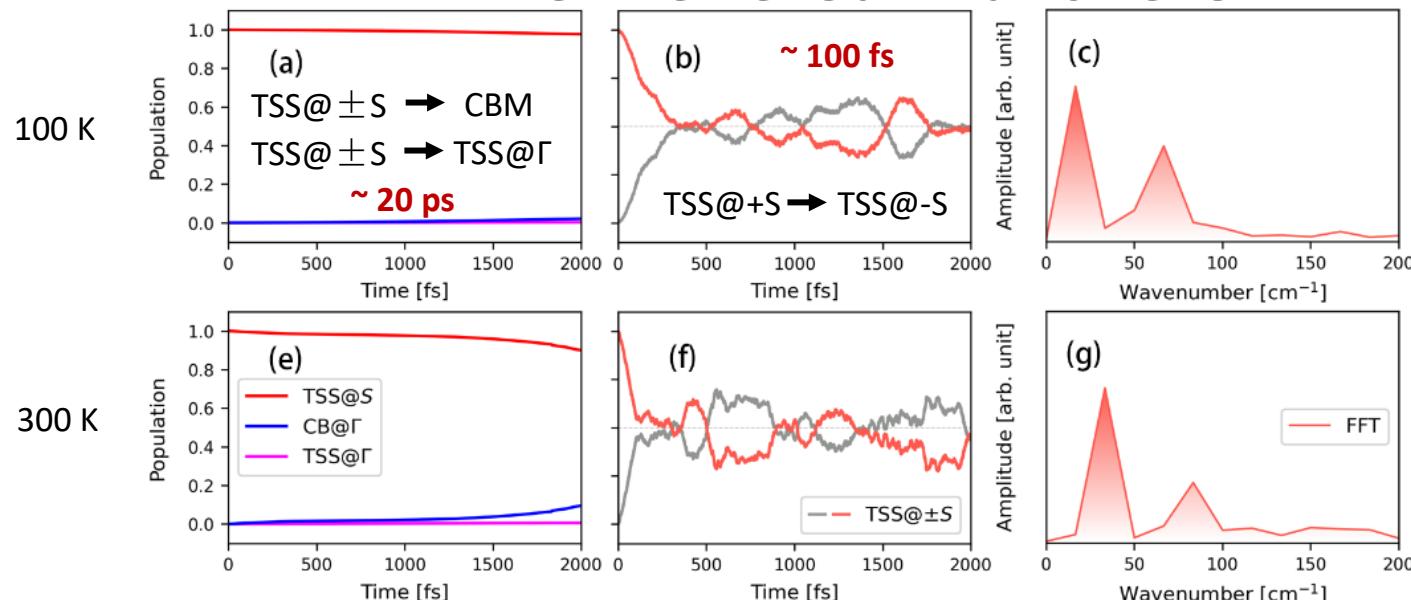
Excited Electron Dynamics in Bi_2Se_3



Back scattering between TSS@ $+S$ and TSS@ $-S$ is forbidden

$$|+> = \mathcal{T}|-> \quad \langle +|U|- \rangle = 0$$

Backscattering Between two TSS@ $\pm S$ Time-Reversal Partners



$$d_{jk} = -i\hbar \left\langle \varphi_j \left| \frac{\partial}{\partial t} \right| \varphi_k \right\rangle = -i\hbar \frac{\left\langle \varphi_j(t) \left| \varphi_k(t + \Delta t) \right\rangle - \left\langle \varphi_j(t + \Delta t) \left| \varphi_k(t) \right\rangle \right)}{2\Delta t}$$

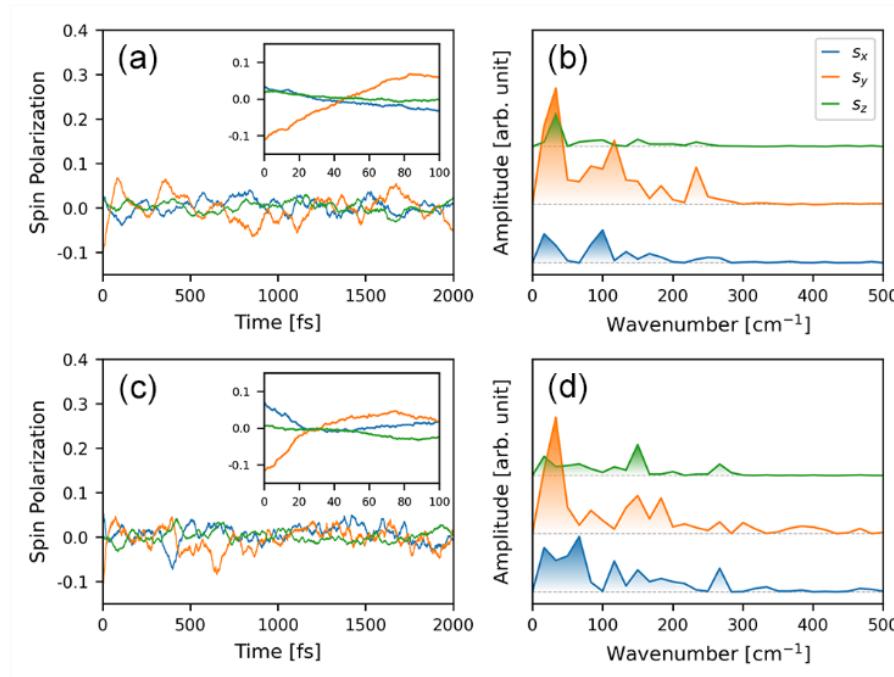
$|+> = \mathcal{T}|->$ $\langle +|U|- \rangle = 0$

Without phonon excitation

$|+, (t + \Delta t)> \neq \mathcal{T}|-, t>$ $\langle +, t|-, (t + \Delta t) \rangle \neq 0$

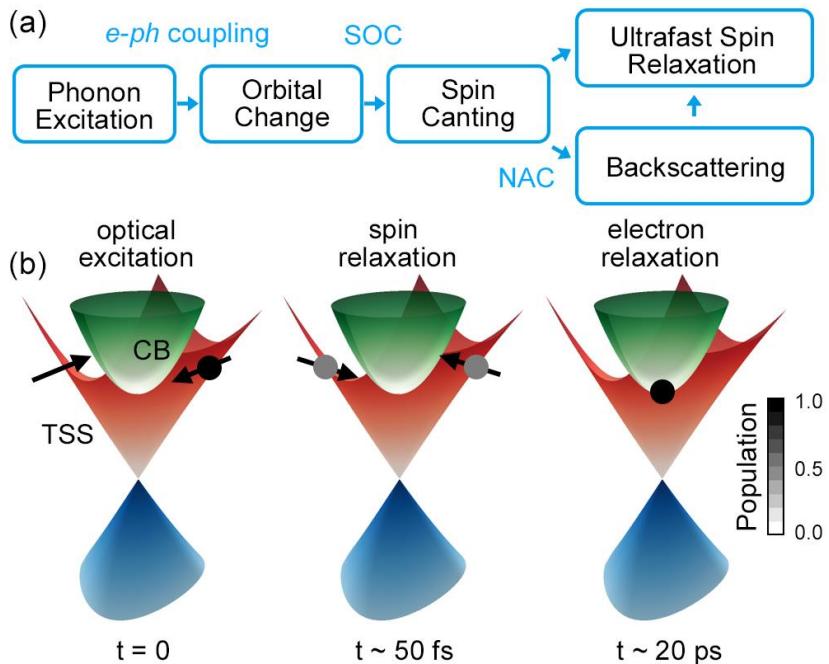
With phonon excitation

Excited State Spin Dynamics in Bi_2Se_3

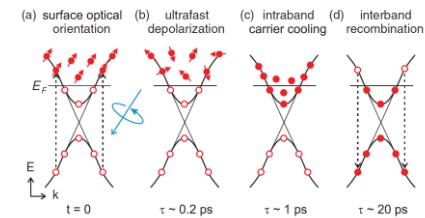


Spin canting occurs in ~ 50 fs

Ultrafast Spin Relaxation of the Excited TSS Electron



C. Zhao, Q. Zheng*, J. Zhao*, *Fundamental Research* in press



N. Gedik* et al. *Phys. Rev. Lett.* 107, 077401 (2011)

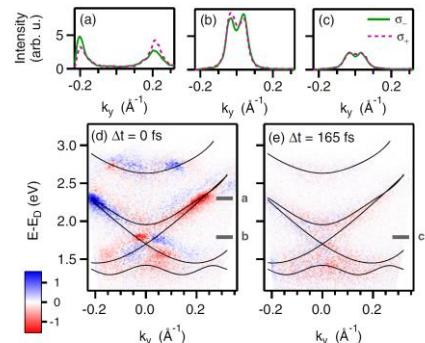


FIG. 2. Helicity-dependent population asymmetry. (a)–(c) Momentum distribution curves (MDCs) of the unoccupied band structure, excited with σ_+ (dashed purple line) and σ_- (solid green line) polarized pulses. (a) and (b) were taken at $\Delta t = 0$, and (c) at $\Delta t = 165 \text{ fs}$, at the energies marked by the short gray lines in (d) and (e). (d),(e) Asymmetry image: Difference between the populations of the unoccupied bands when excited by σ_- and σ_+ polarized pulses, taken at $\Delta t = 0$ and 165 fs respectively. Black lines are guides to the eye that follow the dispersions of the unoccupied bands.

Z. X. Shen* et al. *Phys. Rev. Lett.* 122, 167401 (2019)

Back ground

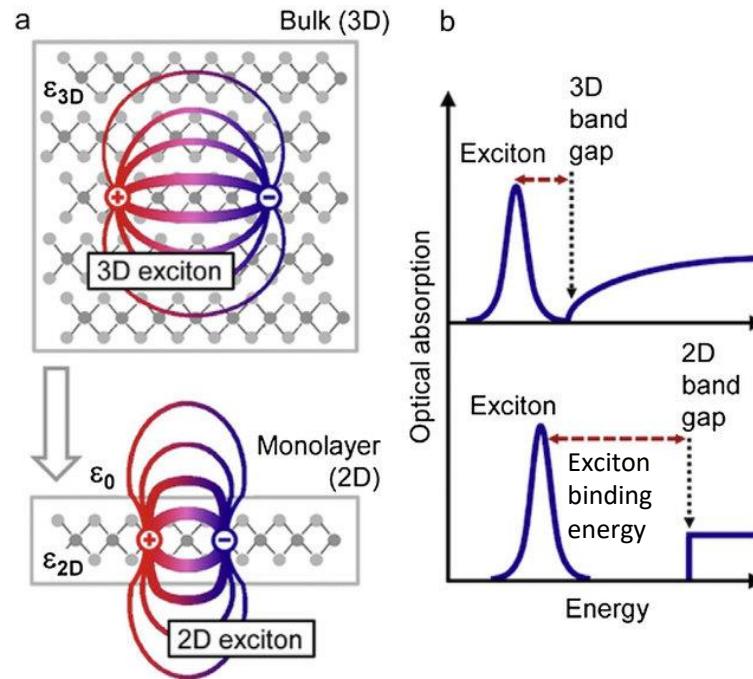
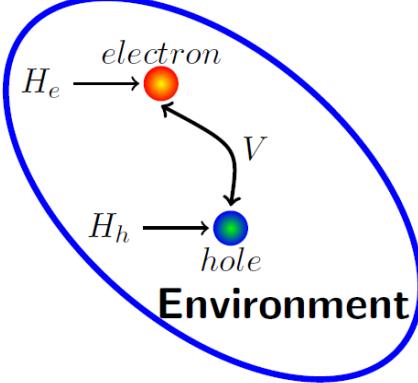
Single particle dynamics

Spin dynamics

Exciton Dynamics

Outlook

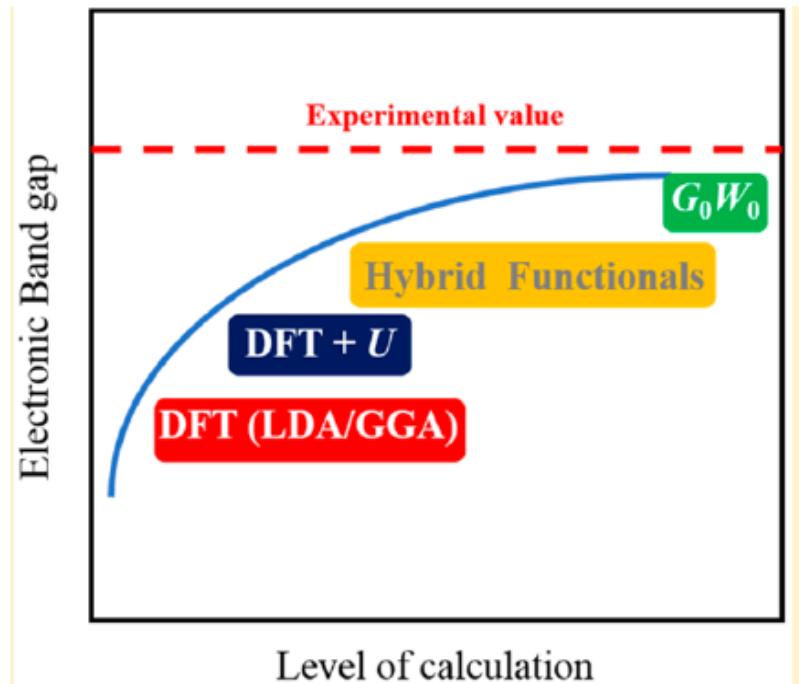
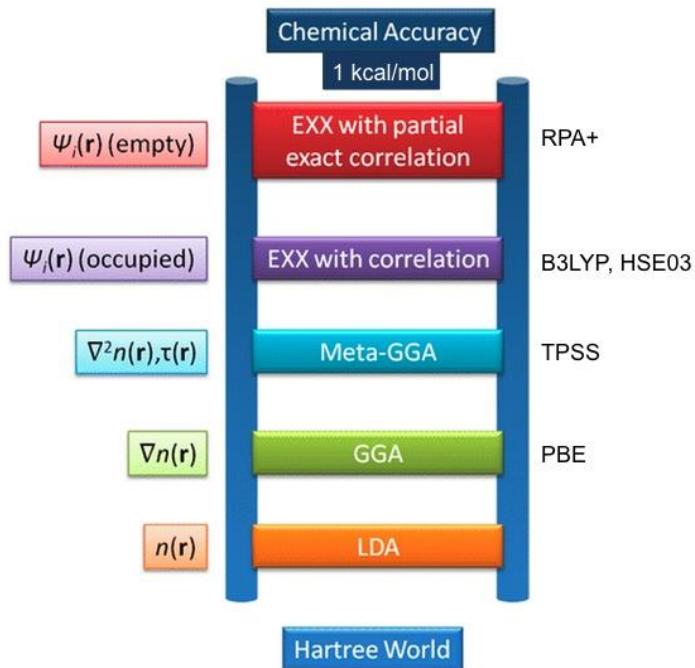
Excitons in 2D Materials



A. Chernikov et al. *Phys. Rev. Lett.* **113** 076802 (2014)

2D materials: quantum confinement significantly reduce the dielectric screening and increase the exciton binding energy

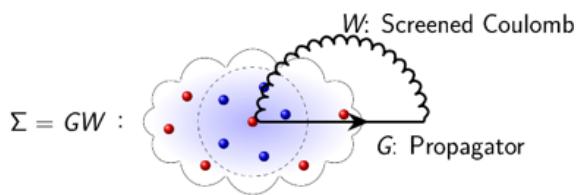
Failure of DFT



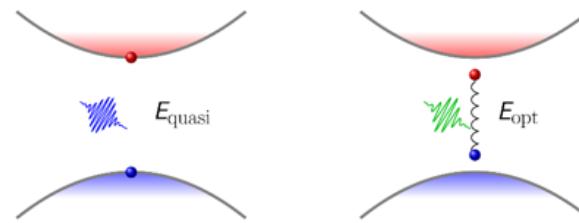
<https://www.sas.upenn.edu/~jianmint/Research/>

A. Morales-Garcia et al. J. Phys. Chem. C, 121, 18862 (2017)

$GW + BSE$ to Describe the Exciton



$$\Sigma^{GW}(\mathbf{r}, \mathbf{r}', \omega) = -\frac{i}{2\pi} \int d\omega e^{i\omega\eta} G(\mathbf{r}, \mathbf{r}', \omega + \omega') W(\mathbf{r}, \mathbf{r}', \omega')$$



$$H_{c'v'k'}^{cvk} = [E_{ck}^{\text{QP}} - E_{vk}^{\text{QP}}] \delta_{cc'} \delta_{vv'} \delta_{kk'} - W_{c'v'k'}^{cvk} + 2v_{c'v'}^{cvk}$$

GW: self-energy take place of exchange correlation potential

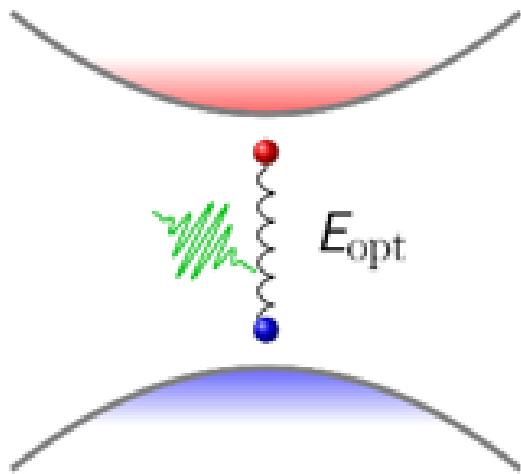


Accurate Quasi-particle energies

Bethe-Salpeter Equation (BSE): Screened Coulomb (W) and exchange (v) interaction of electron and hole

Exciton binding energy and wave function

Exciton Dynamics is Important



Exciton dynamics:

Exciton relaxation

Bright-to-dark transition

Single-to-multi transition

Singlet fission

Exciton annihilation (radiative and nonradiative)

...

10,000 times of GW+BSE calculations are too expensive!

Realization of $GW +$ Real-Time BSE

BSE Hamiltonian: $\langle \mathbf{k}cv | H | \mathbf{k}'c'v' \rangle = (E_{\mathbf{kc}}^{QP} - E_{\mathbf{kv}}^{QP}) \delta_{\mathbf{kk}'} \delta_{cc'} \delta_{vv'} - W_{\mathbf{k}'c'v'}^{\mathbf{k}cv} + v_{\mathbf{k}'c'v'}^{\mathbf{k}cv}.$

Coulomb Interaction: $W_{\mathbf{k}'c'v'}^{\mathbf{k}cv} = \frac{1}{\Omega} \sum_{\mathbf{GG'}} \frac{4\pi \epsilon_{\mathbf{GG'}}^{-1}(\mathbf{k} - \mathbf{k}')}{|\mathbf{k} - \mathbf{k}' + \mathbf{G}| |\mathbf{k} - \mathbf{k}' + \mathbf{G}'|} (B_{\uparrow\mathbf{k}c'}^{\mathbf{k}c}(\mathbf{G}) + B_{\downarrow\mathbf{k}c'}^{\mathbf{k}c}(\mathbf{G})) (B_{\uparrow\mathbf{k}'v'}^{\mathbf{k}v*}(\mathbf{G}') + B_{\downarrow\mathbf{k}'v'}^{\mathbf{k}v*}(\mathbf{G}'))$

Exchange Interaction: $v_{\mathbf{k}'c'v'}^{\mathbf{k}cv} = \frac{1}{\Omega} \sum_{\mathbf{G} \neq 0} \frac{4\pi}{|\mathbf{G}|^2} (B_{\uparrow\mathbf{k}c}^{\mathbf{k}c}(\mathbf{G}) + B_{\downarrow\mathbf{k}c}^{\mathbf{k}c}(\mathbf{G})) (B_{\uparrow\mathbf{k}'c'*}^{\mathbf{k}c'*}(\mathbf{G}) + B_{\downarrow\mathbf{k}'c'*}^{\mathbf{k}c'*}(\mathbf{G})),$

Rigid dielectric function during MD

10,000 real-time $GW + BSE$ – 1 $GW +$ real-time BSE

QP energy: Rigid shift from KS energy

Realization of GW + Real-Time BSE

Single-particle

TDDFT

$$i\hbar \frac{\partial \psi(r, t)}{\partial t} = \mathcal{H}(r; R)\psi(r, t)$$



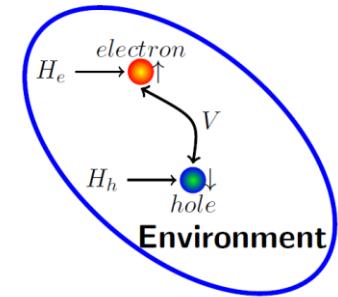
Real-time - BSE

$$i\hbar \frac{\partial \psi(r_e, r_h, t)}{\partial t} = \mathcal{H}(r; R)\psi(r_e, r_h, t)$$

two-particle

Hamiltonian:

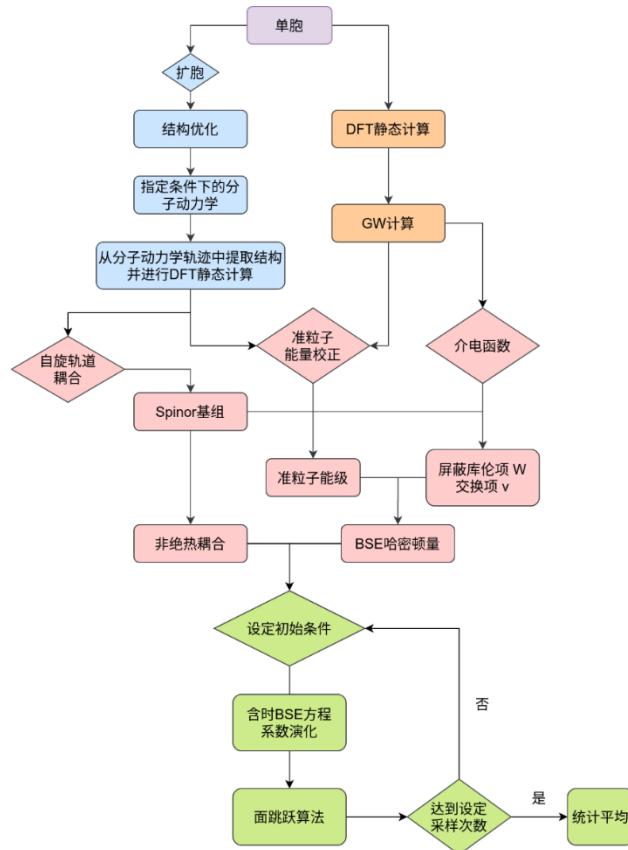
$$H = H_e + H_h + V_{e-h} + H^{SO}$$



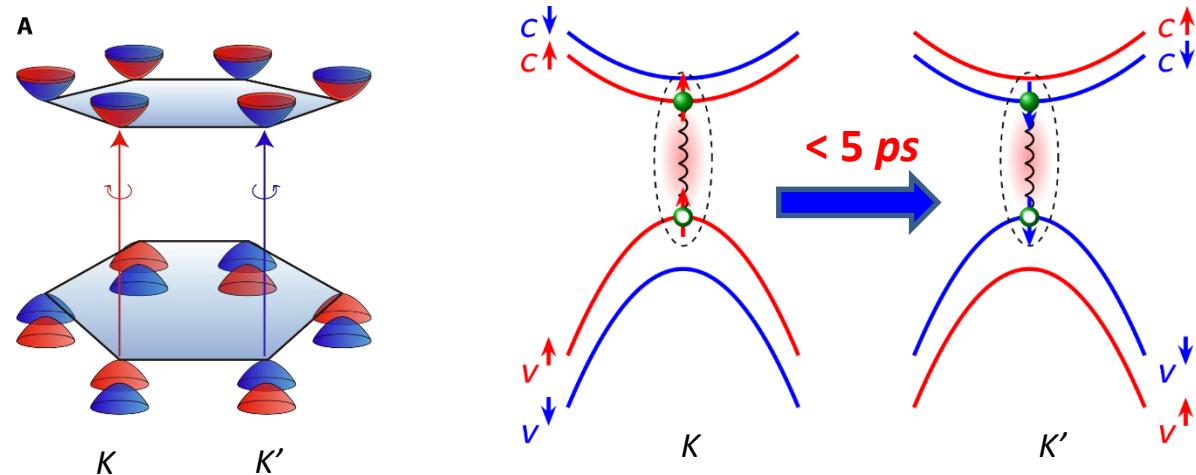
Spin orbital coupling

- ✓ **Many-body interaction:** Coulomb and exchange
- ✓ **Exciton-phonon interaction:** real-time BSE + molecular dynamics
- ✓ **Spin orbital coupling:** adiabatic and diabatic representation
- ✓ **Nonadiabatic:** surface hopping

含时激子动力学方法实现



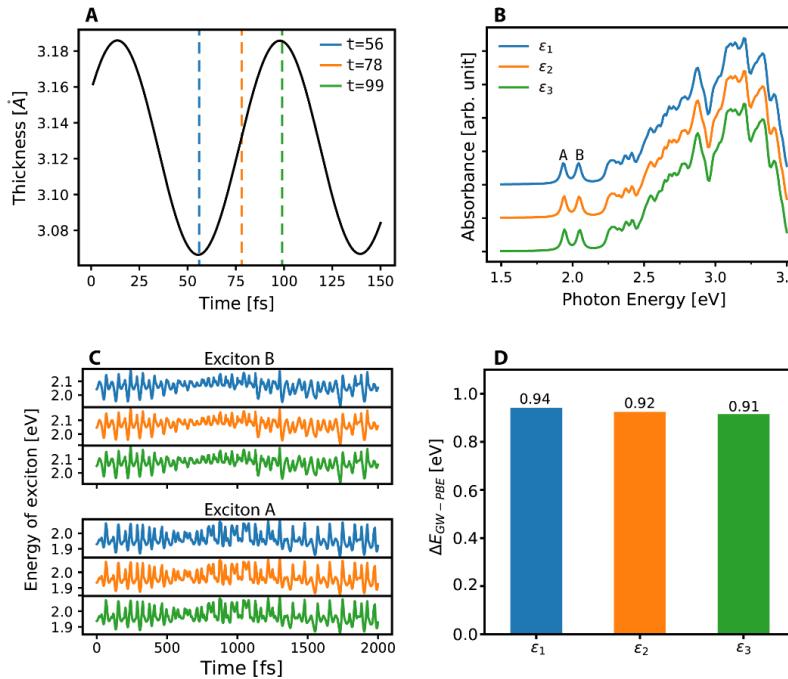
Fast Intervalley Bright Exciton Scattering in Transition Metal Dichalcogenide



Intervalley bright exciton scattering requires the **spin flip and momentum transition of both electron and hole**

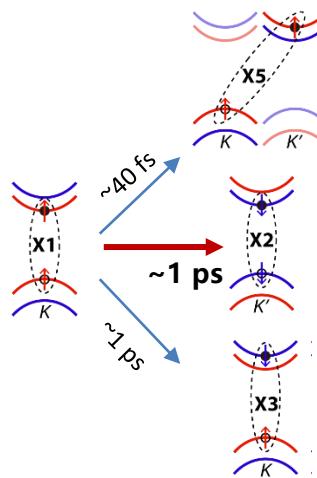
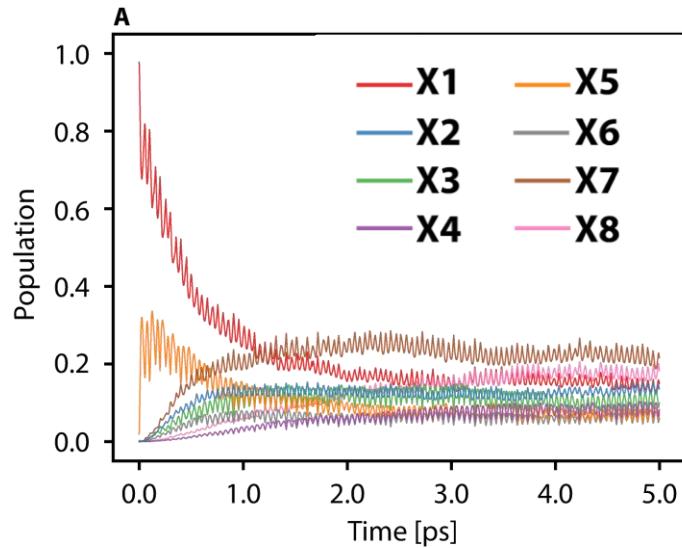
Puzzle: how can such intervalley bright exciton happen within **several picoseconds?**

Test of the Dielectric Function Approximation

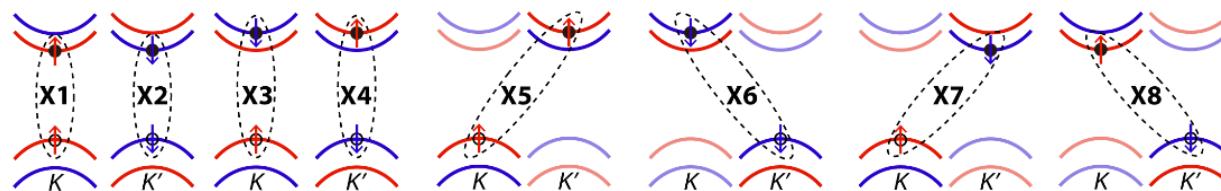


The dielectric function and ***GW*QP correction almost does not change with the structure**

Exciton Dynamics in MoS₂



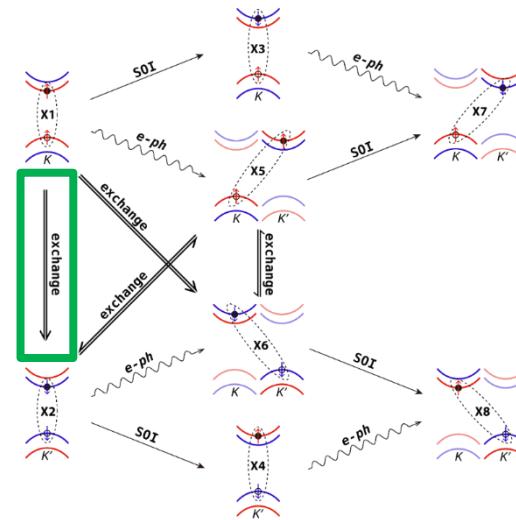
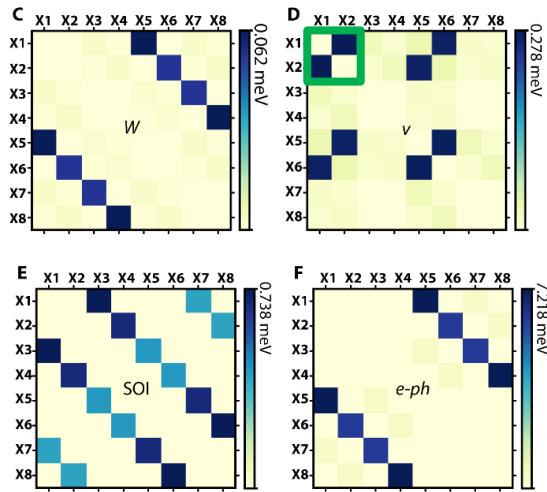
Bright Exciton
transition happens
in several ps



Exchange Interaction Induced Bright Exciton Scattering

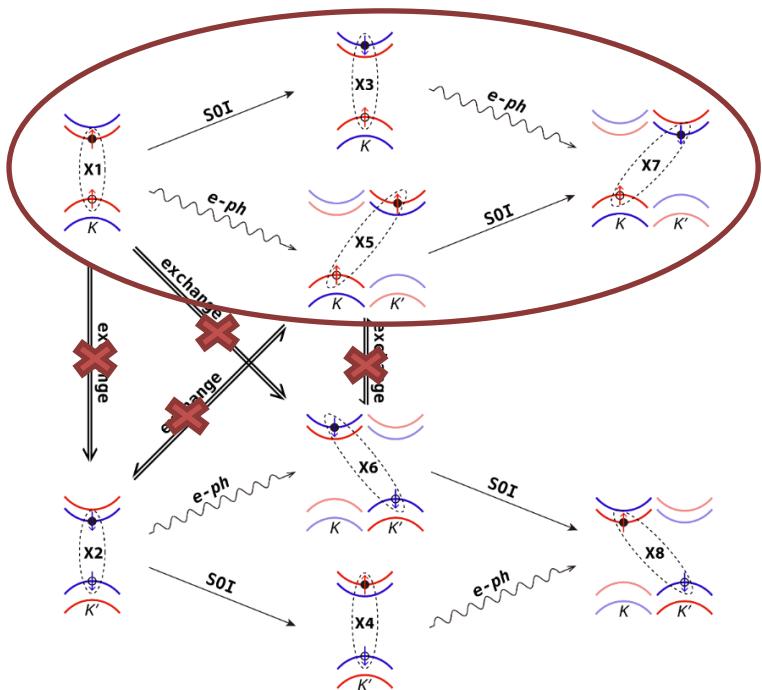
Nonadiabatic Coupling Elements:

Single particle dynamics: $e\text{-}ph$
Exciton dynamics: $e\text{-}ph + W(e\text{-}h \text{ Coulomb}) + v(e\text{-}h \text{ exchange}) + \text{SOC}$

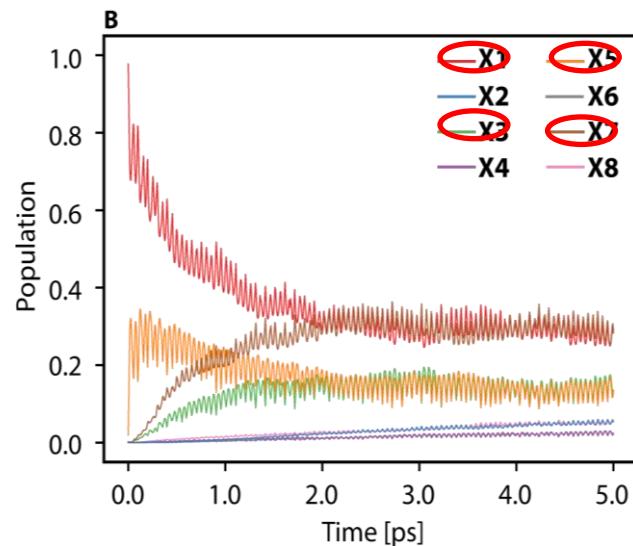


Bright Exciton transition is induced by $e\text{-}h$ exchange interaction

Single Particle Picture



Spin particle picture: photoexcited hole keeps in K valley



Summary

Single-particle

TDDFT

$$i\hbar \frac{\partial \psi(r, t)}{\partial t} = \mathcal{H}(r; R)\psi(r, t)$$



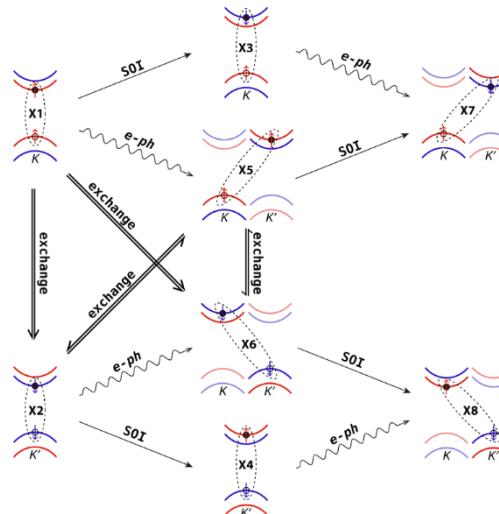
Real-time - BSE

$$i\hbar \frac{\partial \psi(r_e, r_h, t)}{\partial t} = \mathcal{H}(r; R)\psi(r_e, r_h, t)$$

two-particle

- ✓ Many-body interaction
- ✓ Exciton-phonon interaction
- ✓ Spin orbital coupling
- ✓ Nonadiabatic effects

X. Jiang, Q. Zheng, Z. Lan, W. A. Saidi, X. Ren and J. Zhao* *Sci. Adv.*, **7**, eabf3759, (2021)



Xiang Jiang
蒋翔

nature computational science



Protecting against racial
profiling in DNA databases

research highlights



Check for updates

TWO-DIMENSIONAL MATERIALS

Computationally probing exciton dynamics

Sci. Adv. **7**, eabf3759 (2021)

Light-matter interactions are essential to many optical and optoelectronic applications, such as solar-to-electrical energy conversion. When light sheds on a semiconductor material, an electron-hole ($e-h$) pair can be created. In semiconductor physics, a hole defines a

This team of researchers developed their computational method by integrating the ab initio non-adiabatic molecular dynamics (NAMD), the GW method, and real-time evolution of the Bethe-Salpeter equation (BSE); they named their method as $GW + rtBSE + NAMD$. In their framework,

Back ground

Single particle dynamics

Spin dynamics

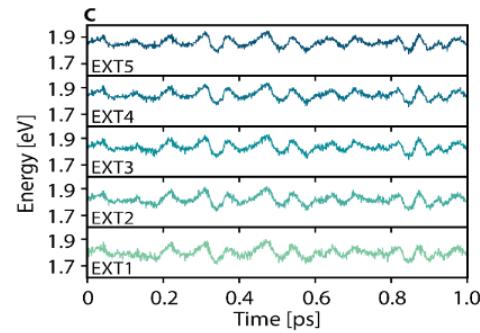
Exciton Dynamics

Outlook

What can be Done Using the GW-rtBSE NAMD Simulation

- ✓ Exciton Lifetime
- ✓ Hot exciton Relaxation
- ✓ Exciton transition
 - at interface
 - via spin valley
 - bright-to-dark

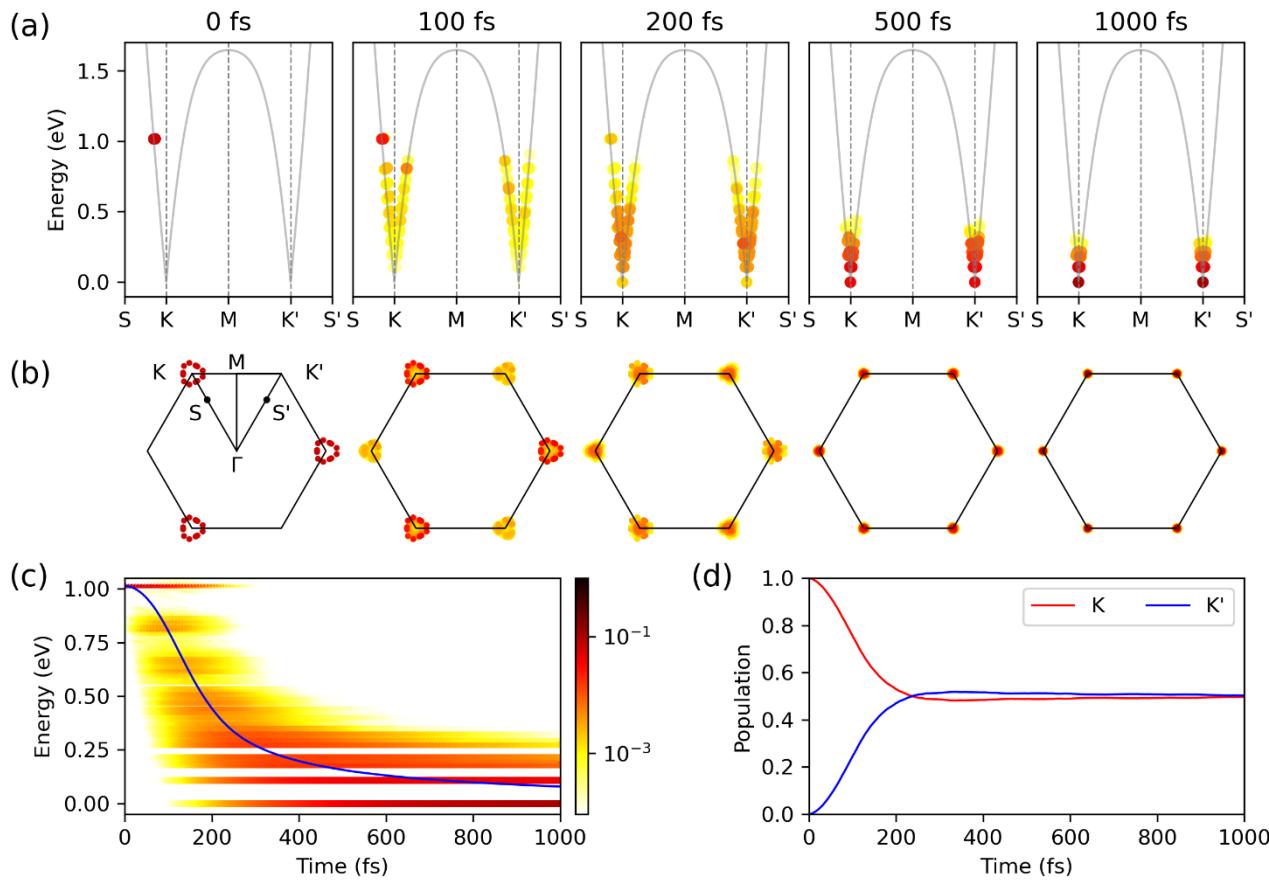
...
- ✓ Exciton-Phonon Interaction
- ✓ Exciton-Polaron interaction
- ✓ Excited state potential surface from machine learning



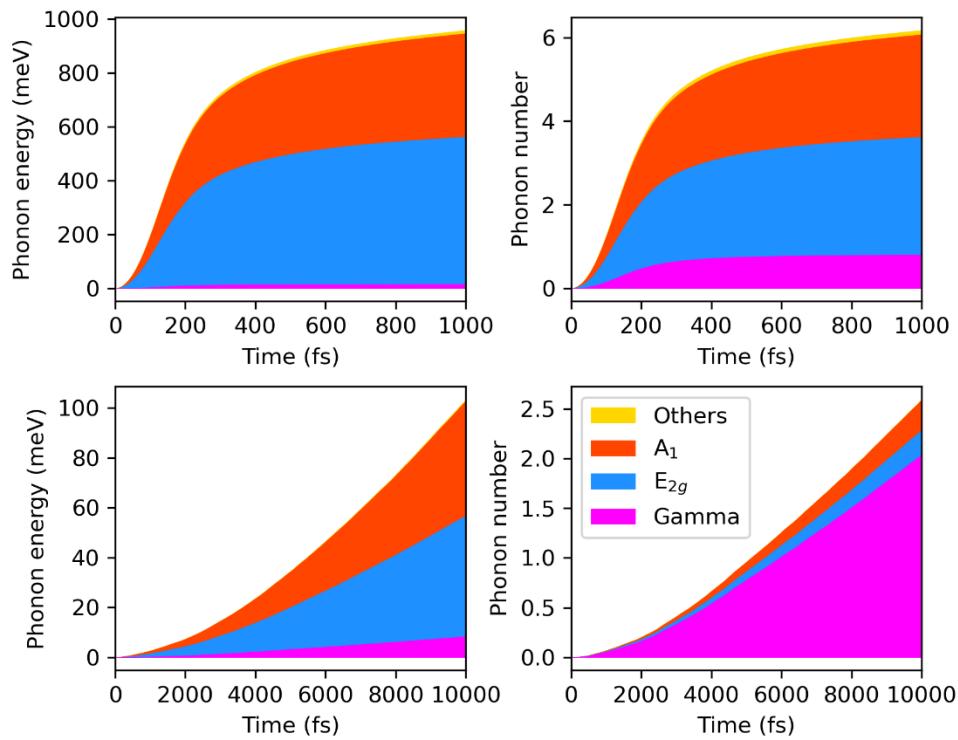
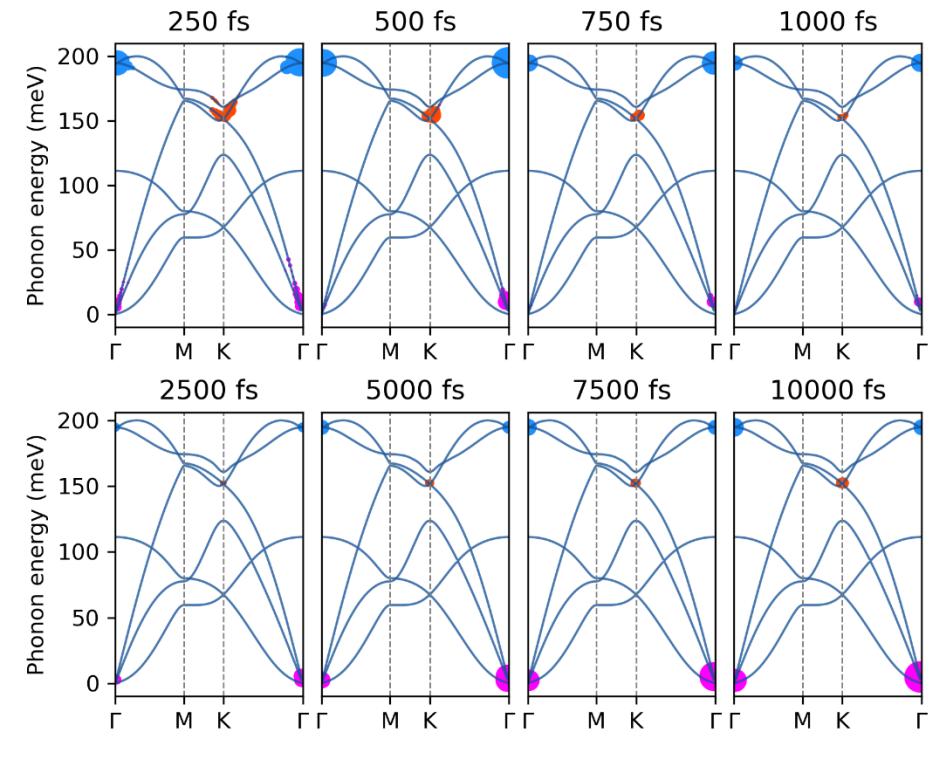
Several thousands of exciton energies can be used for machine learning

{ Photo-induced phase transition
Photocatalysis

NAMD Simulation in Momentum Space

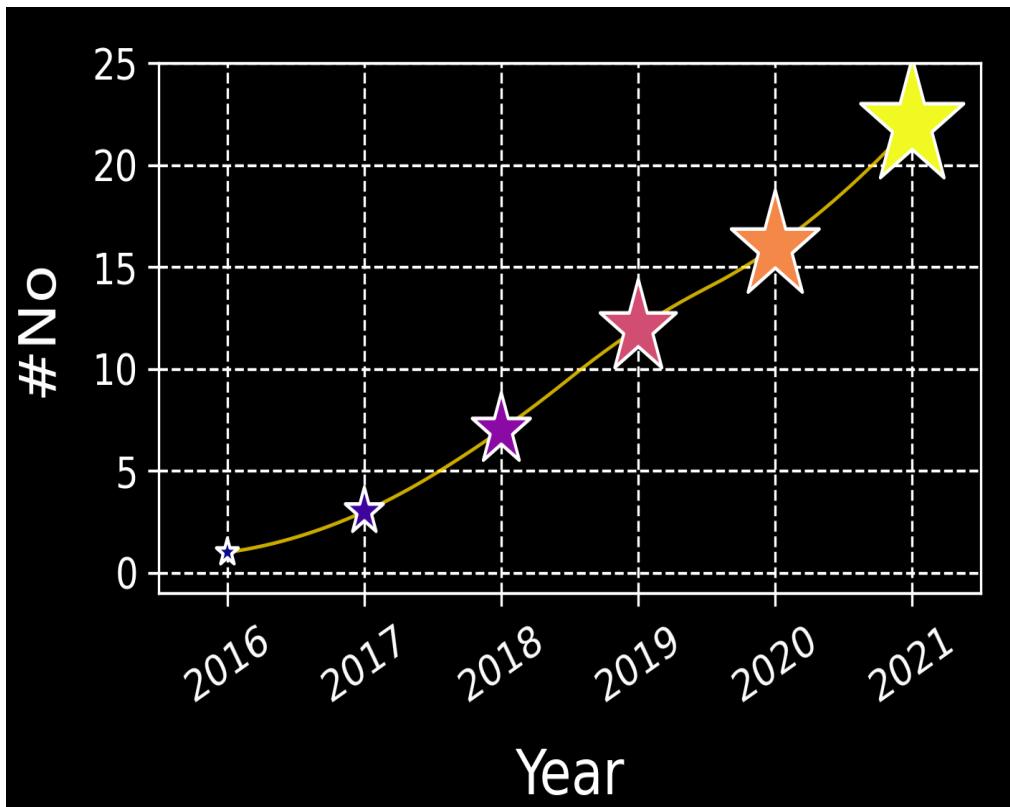


Phonon Excitation



Hefei-NAMD的应用与推广

Publications by Hefei-NAMD (over 80)

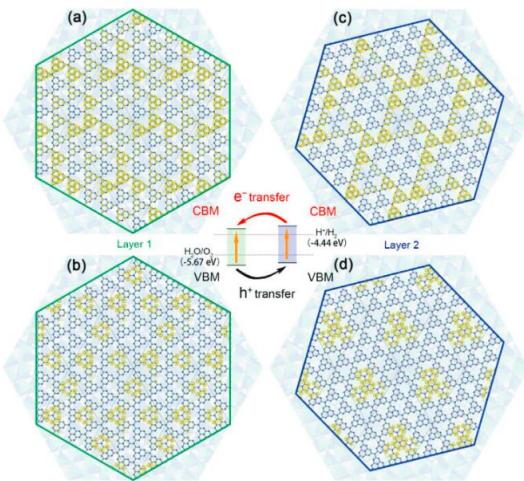


Journal	Number of Publications
Sci. Adv.	3
Nat. Commun.	1
Phys. Rev. Lett.	3
JACS	2
Adv. Mater.	1
Nano Lett.	4
ACS NANO	1
J. Phys. Chem. Lett.	18
Chem. Sci.	1
Angew Chem.	1

RESEARCH ARTICLE

Ultrafast Interlayer Charge Separation, Enhanced Visible-Light Absorption, and Tunable Overpotential in Twisted Graphitic Carbon Nitride Bilayers for Water Splitting

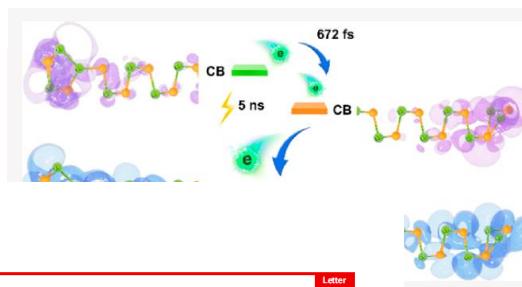
Xirui Zhang, Tong Wu, Chao Yu, and Ruijeng Lu*



南京理工大学陆瑞峰

Universal Zigzag Edge Reconstruction of an α -Phase Puckered Monolayer and Its Resulting Robust Spatial Charge Separation

Yanxue Zhang, Yanyan Zhao, Yizhen Bai, Junfeng Gao,* Jijun Zhao, and Yong-Wei Zhang*



大连理工大学高峻峰

Two Dimensional MOene: From Superconductors to Direct Semiconductors and Weyl Fermions

Luo Yan, Jiaojiao Zhu, Bao-Tian Wang, Junjie He, Hai-Zhi Song, Weibin Chu, Sergei Tretiak, and Luijiang Zhou*

Cite This: <https://doi.org/10.1021/acs.nanolett.2c01914>

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Supporting Information

ABSTRACT: The number of semiconducting MXenes with direct band gaps is extremely low; thus, it is highly desirable to broaden the MXene family beyond carbides and nitrides to expand the palette of desired chemical and physical properties. Here, we theoretically report the existence of the single-layer (SL) dinitrogen oxide 2H-Ti₂O MOene (MXene-like 2D transition metal dinitrogen oxide monolayer) featuring topological insulator-like gap opening and Weyl fermion nodes. Specifically, halogenated 2H- and 1T-Ti₂O monolayers display tunable semiconducting features and strong light-harvesting ability. In addition, the external strains can induce Weyl fermions via quantum phase transition in 2H-Ti₂O_x and Ti₂OCl₂ monolayers. Specifically, 2H- and 1T-Ti₂O_x are direct semiconductors with band gaps of 0.82 and 1.18 eV, respectively. Furthermore, the carrier lifetimes of SL 2H- and 1T-Ti₂O_x are evaluated to be 0.39 and 2.8 ns, respectively. This study extends emerging phenomena in a rich family of 2D MXene-like MOene materials, which provides a novel platform for next-generation optoelectronic and photovoltaic fields.

KEYWORDS: MXene-like MOene, halogenation, quantum phase transition, exciton, nonadiabatic molecular dynamics

电子科大周柳江

Reference & Developers

Video

Hefei-NAMD使用的一些经验

<https://www.koushare.com/video/videodetail/11720>

Hefei-NAMD基本流程介绍

<https://www.bilibili.com/video/BV1p5411c7RS>

Hefei-NAMD培训

<https://www.koushare.com/lives/room/341102>

Website:

<http://staff.ustc.edu.cn/~zqj>

<http://staff.ustc.edu.cn/~zhaojin>

<https://github.com/QijingZheng>

<https://github.com/WeibinChu>

Developers:

Dr. Qijing Zheng (郑奇靖), zqj@ustc.edu.cn

Mr. Xiang Jiang (蒋翔), jxiang@mail.ustc.edu.cn, exciton dynamics

Dr. Weibin Chu (褚维斌), wbchu@ustc.edu.cn, CA-NAC, DISH

Dr. Chuanyu Zhao (赵传寓), zhaochuanyu@zju.edu.cn, DISH

Mr. Zhenfa Zheng (郑镇法), zzfgjs@mail.ustc.edu.cn, Dynamics in momentum space

Determining Factors of Carrier Dynamics

No perturbation, no relaxation : $\langle \psi_i | \psi_j \rangle = 0$

With perturbation:

$$\langle \psi_i | B | \psi_i \rangle$$

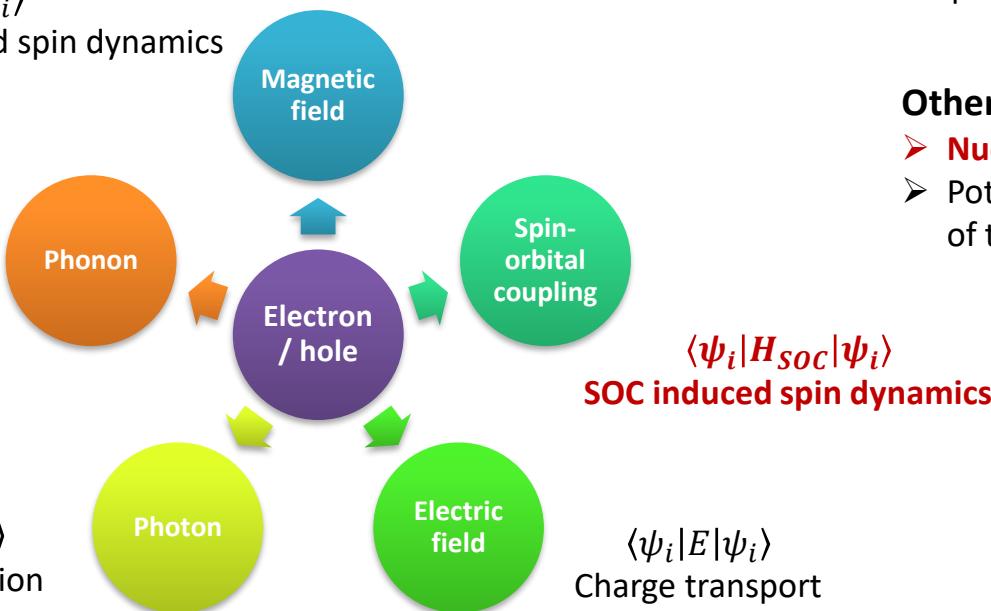
Magnetic field induced spin dynamics

$$\left\langle \psi_i \left| \frac{\partial}{\partial t} \right| \psi_i \right\rangle$$

Nonradiative relaxation

$$\langle \psi_i | E e^{i\omega t} | \psi_i \rangle$$

Radiative relaxation



Many-body effects:

- e-e interaction
- **e-h interaction (exciton effects)**
- spin-spin interaction

Other effects:

- **Nuclear quantum effects**
- Potential energy surface of the excited state



郑奇靖
中科大副教授



褚维斌
复旦大学青年研究员



蒋翔
UC Irvine 博后



郑镇法
博士生



史永亮
华为



张丽丽
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赵传寓
腾讯



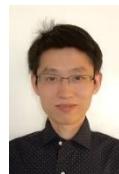
兰峥岗
华南师大
Surface hopping



李新征
北京大学
PIMD



任新国
中科院物理所
GW+BSE



谭世倞
中科大
实验



王兵
中科大
实验



Hrvoje Petek
匹兹堡大学
实验



杨金龙
中科大
讨论+支持

感谢基金委、科技部、中国科大的经费支持